Tutorial on Memory-Centric Computing: Introduction

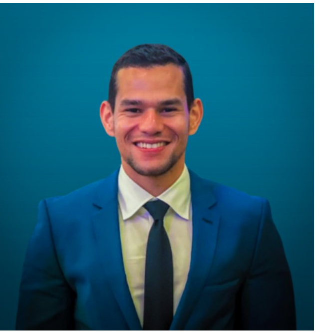
Geraldo F. Oliveira
Prof. Onur Mutlu

HEART 2024
21 June 2024

SAFARI

ETH zürich

Brief Self Introduction



- Geraldo F. Oliveira
  - Researcher @ SAFARI Research Group since November 2017
  - Soon, I will defend my PhD thesis, advised by Onur Mutlu
  - https://geraldofojunior.github.io/
  - geraldofojunior@gmail.com (Best way to reach me)
  - https://safari.ethz.ch

- Research in:
  - Computer architecture, computer systems, hardware security
  - Memory and storage systems
  - Hardware security, safety, predictability
  - Fault tolerance
  - Hardware/software cooperation
  - ...

Agenda

- Introduction to Memory-Centric Computing Systems
- Real-World Processing-Near-Memory Systems
- Processing-Using-Memory Architectures for Bulk Bitwise Operations
- Lunch Break
- PIM Programming & Infrastructure for PIM Research
- Tentatively: Hands-on Lab on Programming and Understanding a Real Processing-in-Memory Architecture

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The Problem

Computing

is Bottlenecked by Data

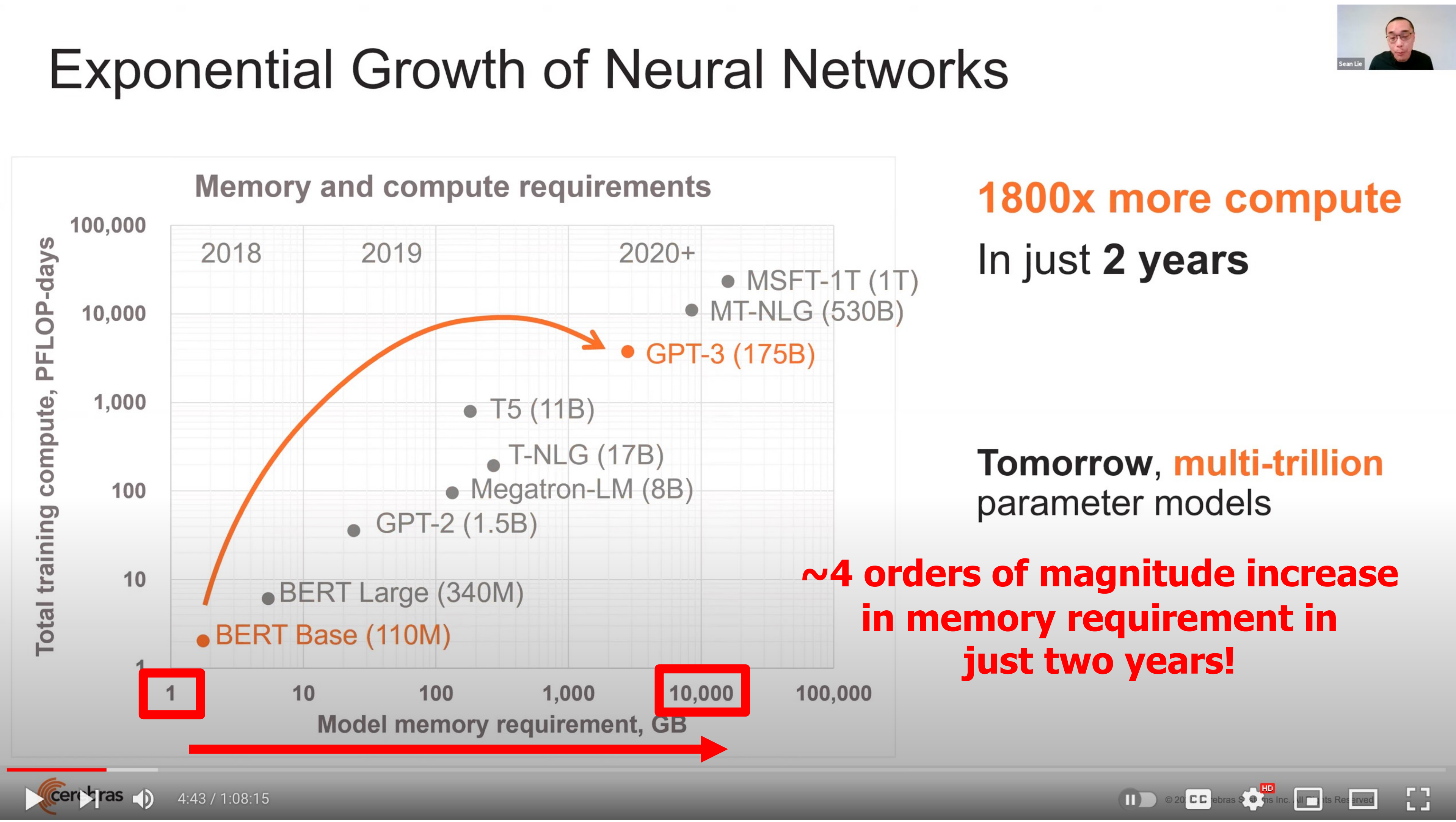
Data is Key for AI, ML, Genomics, …

- Important workloads are all data intensive

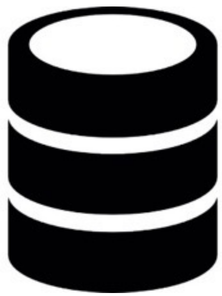
- They require rapid and efficient processing of large amounts of data

- Data is increasing
  - We can generate more than we can process
  - We need to perform more sophisticated analyses on more data

Huge Demand for Performance & Efficiency



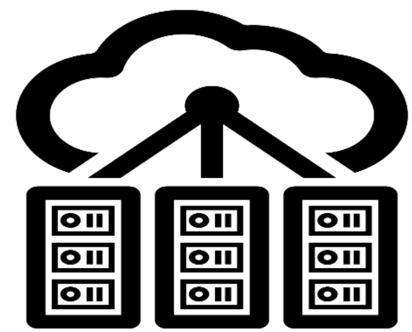
Data is Key for Future Workloads



In-memory Databases
[Mao+, EuroSys'12;
Clapp+ (**Intel**), IISWC'15]

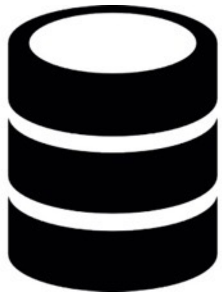
Graph/Tree Processing
[Xu+, IISWC'12; Umuroglu+, FPL'15]

In-Memory Data Analytics
[Clapp+ (**Intel**), IISWC'15;
Awan+, BDCloud'15]



Datacenter Workloads
[Kanev+ (**Google**), ISCA'15]

Data Overwhelms Modern Machines



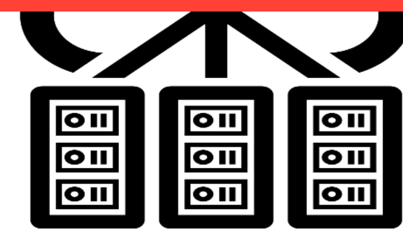
In-memory Databases

Graph/Tree Processing

Data → performance & energy bottleneck

In-Memory Data Analytics

[Clapp+ (**Intel**), IISWC'15;
Awan+, BDCloud'15]



Datacenter Workloads

[Kanev+ (**Google**), ISCA'15]

Data is Key for Future Workloads

Chrome

Google's web browser

TensorFlow Mobile

Google's machine learning framework

Video Playback

Google's video codec

Video Capture

Google's video codec

Data Overwhelms Modern Machines

Chrome

TensorFlow Mobile

Data → performance & energy bottleneck

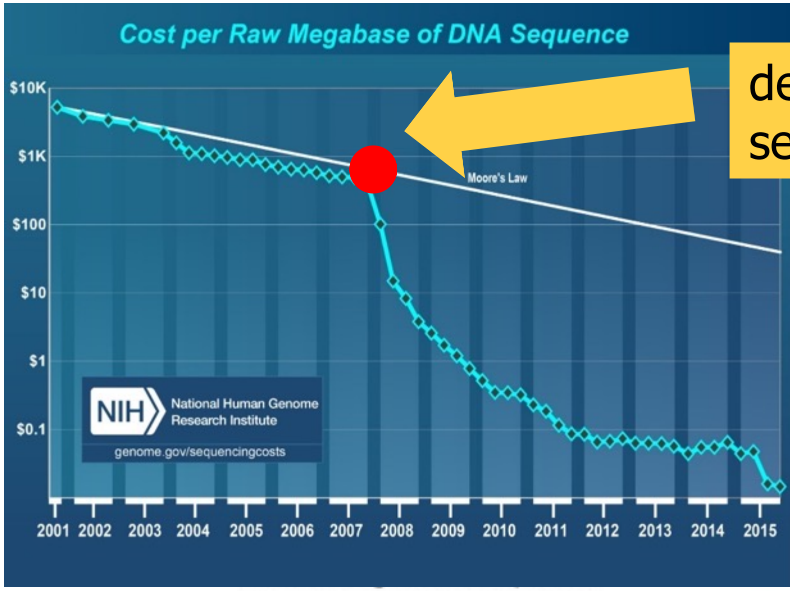
Video Playback

Google's **video codec**

Video Capture

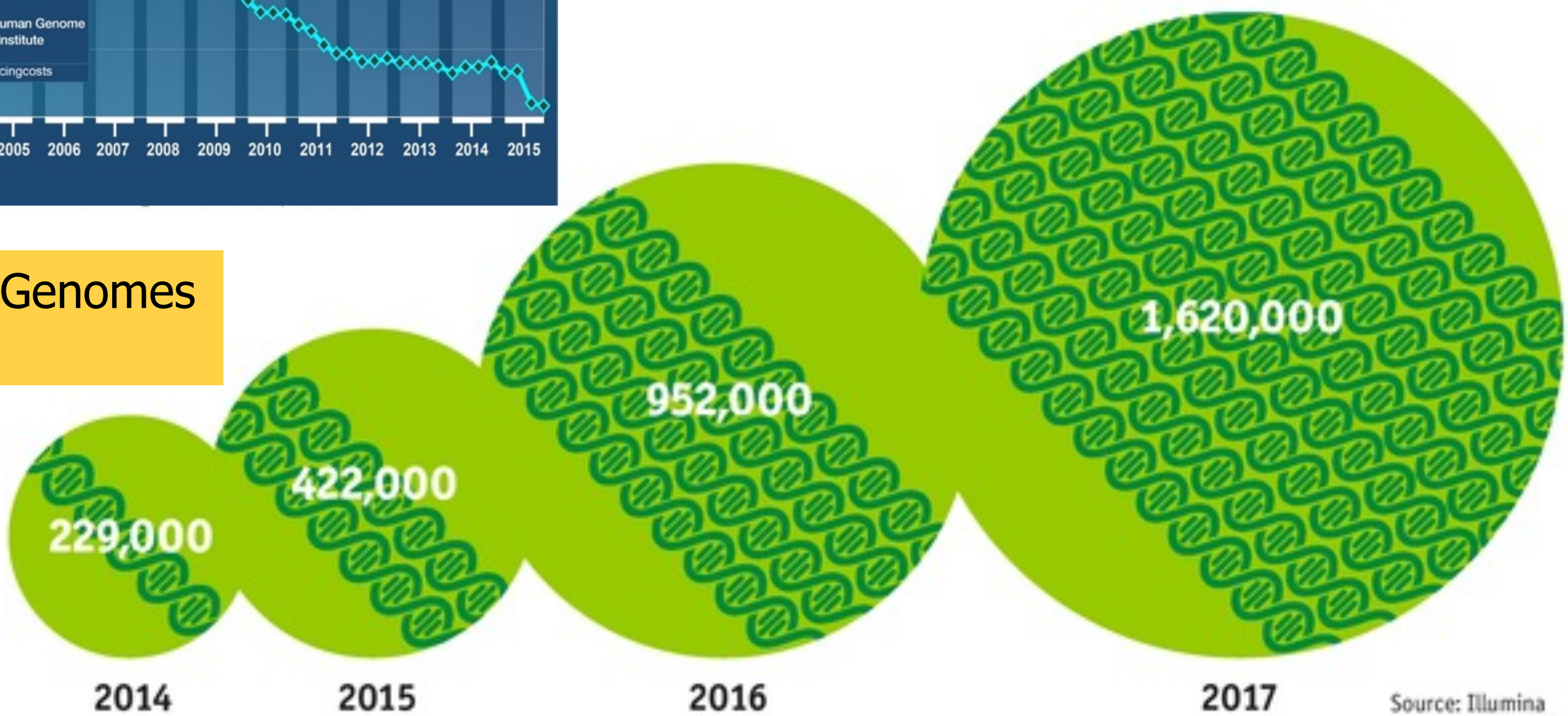
Google's **video codec**

Data is Key for Future Workloads

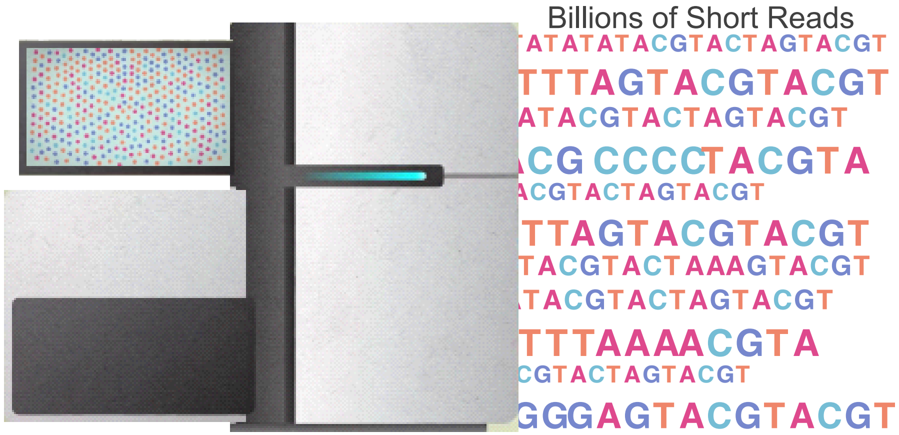


development of high-throughput sequencing (HTS) technologies

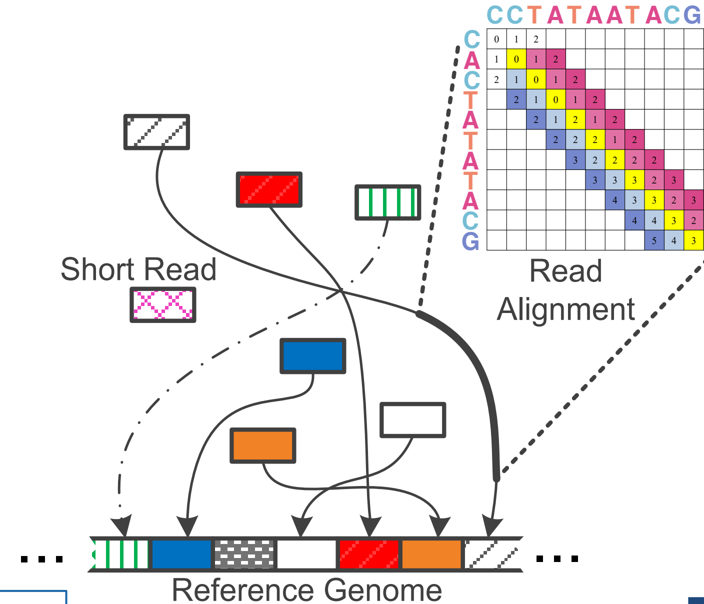
Number of Genomes Sequenced



The Economist



1 Sequencing



Read Mapping 2

Genome Analysis

Data → performance & energy bottleneck

```
read4:          CGCTTCCAT
read5:                  CCATGACGC
read6:              TTCCATGAC
```

3 Variant Calling

Scientific Discovery 4

Data Overwhelms Modern Machines …

- Storage/memory capability

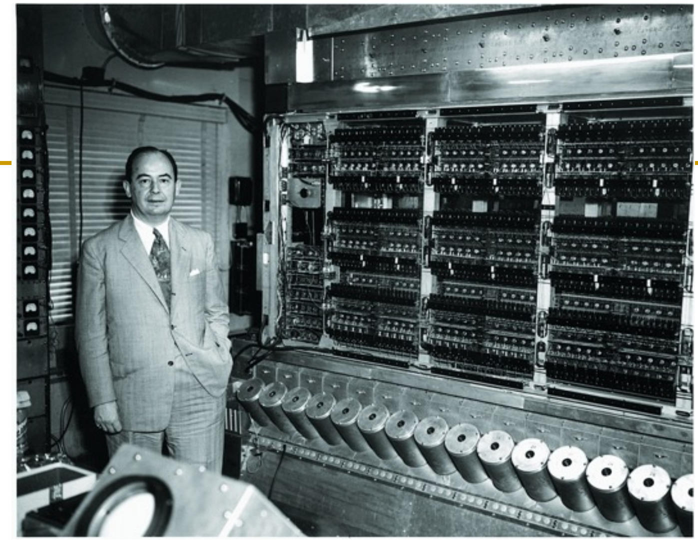
- Communication capability

- Computation capability

- Greatly impacts robustness, energy, performance, cost

A Computing System

- Three key components
- Computation
- Communication
- Storage/memory



Burks, Goldstein, von Neumann, "Preliminary discussion of the logical design of an electronic computing instrument," 1946.

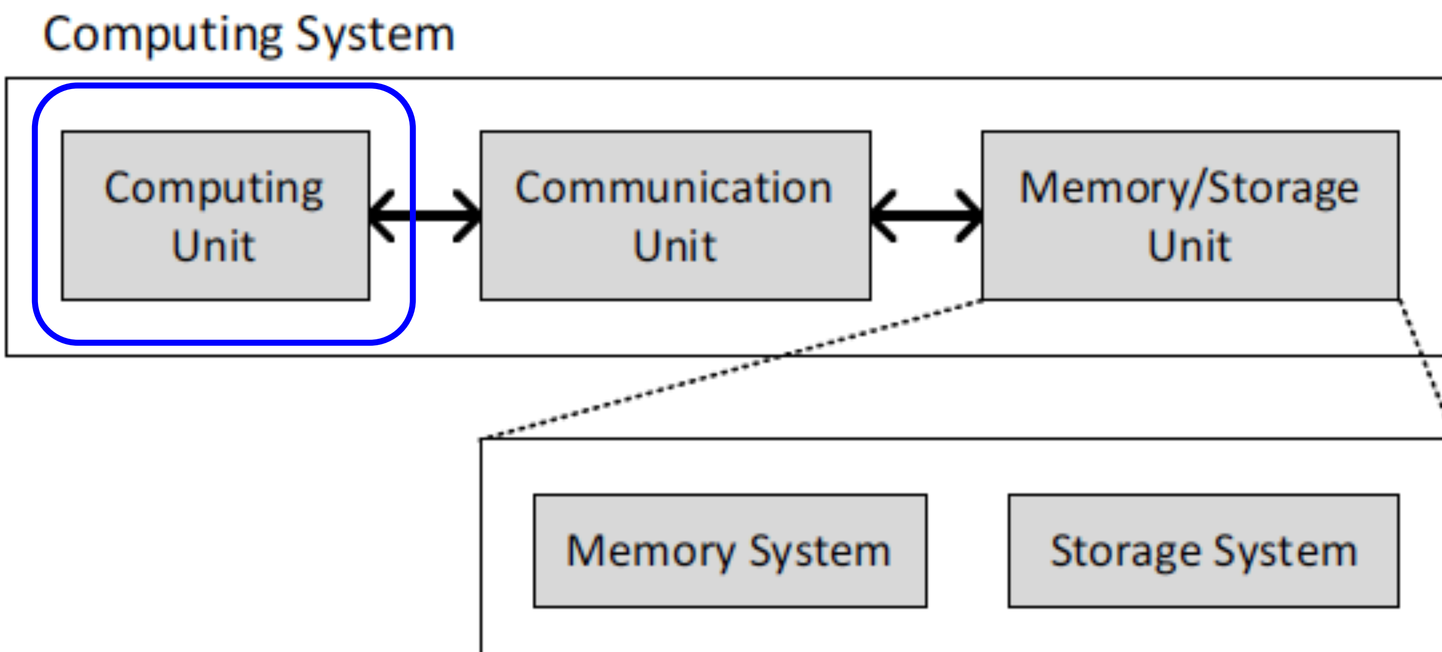
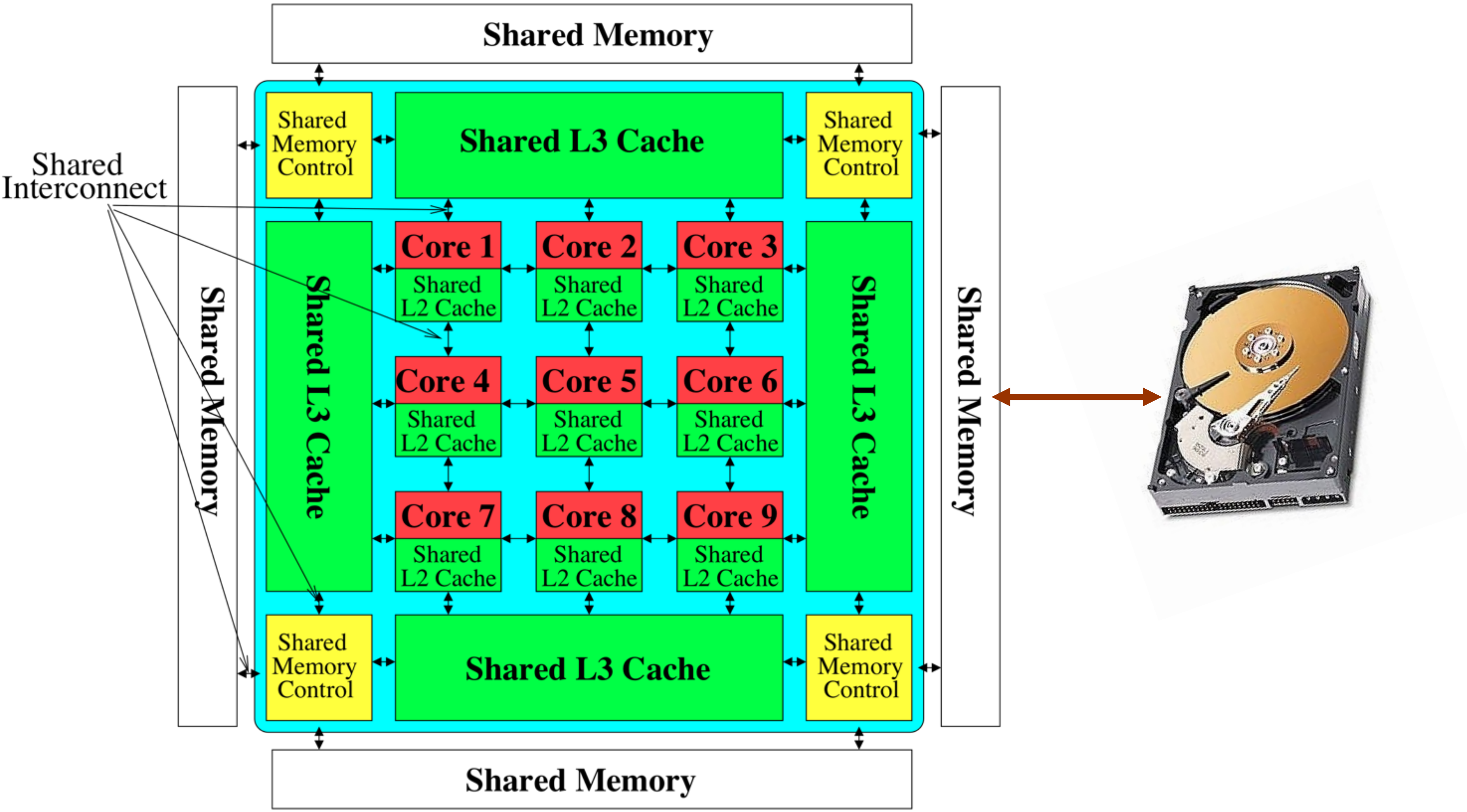


Image source: https://lbsitbytes2010.wordpress.com/2013/03/29/john-von-neumann-roll-no-15/

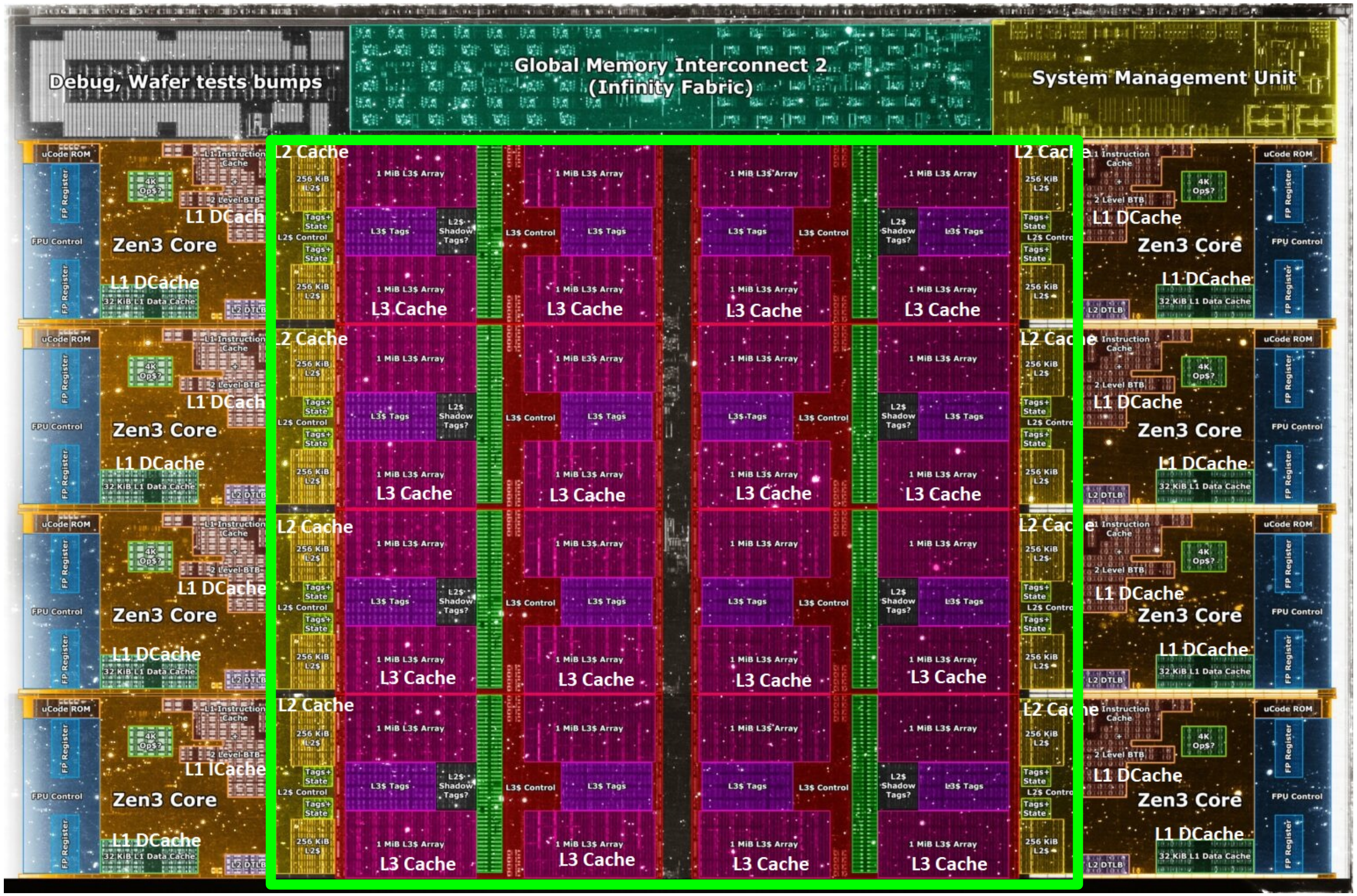
Perils of Processor-Centric Design



Most of the system is dedicated to storing and moving data

Yet, system is still bottlenecked by memory

A Solution: Deeper and Larger Memory Hierarchies



AMD Ryzen 5000, 2020

Core Count:
8 cores/16 threads

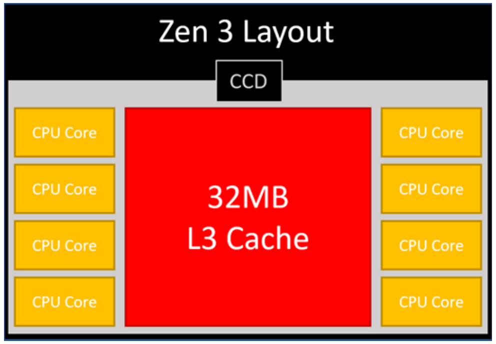
L1 Caches:
32 KB per core

L2 Caches:
512 KB per core

L3 Cache:
32 MB shared

https://wccftech.com/amd-ryzen-5000-zen-3-vermeer-undressed-high-res-die-shots-close-ups-pictured-detailed/

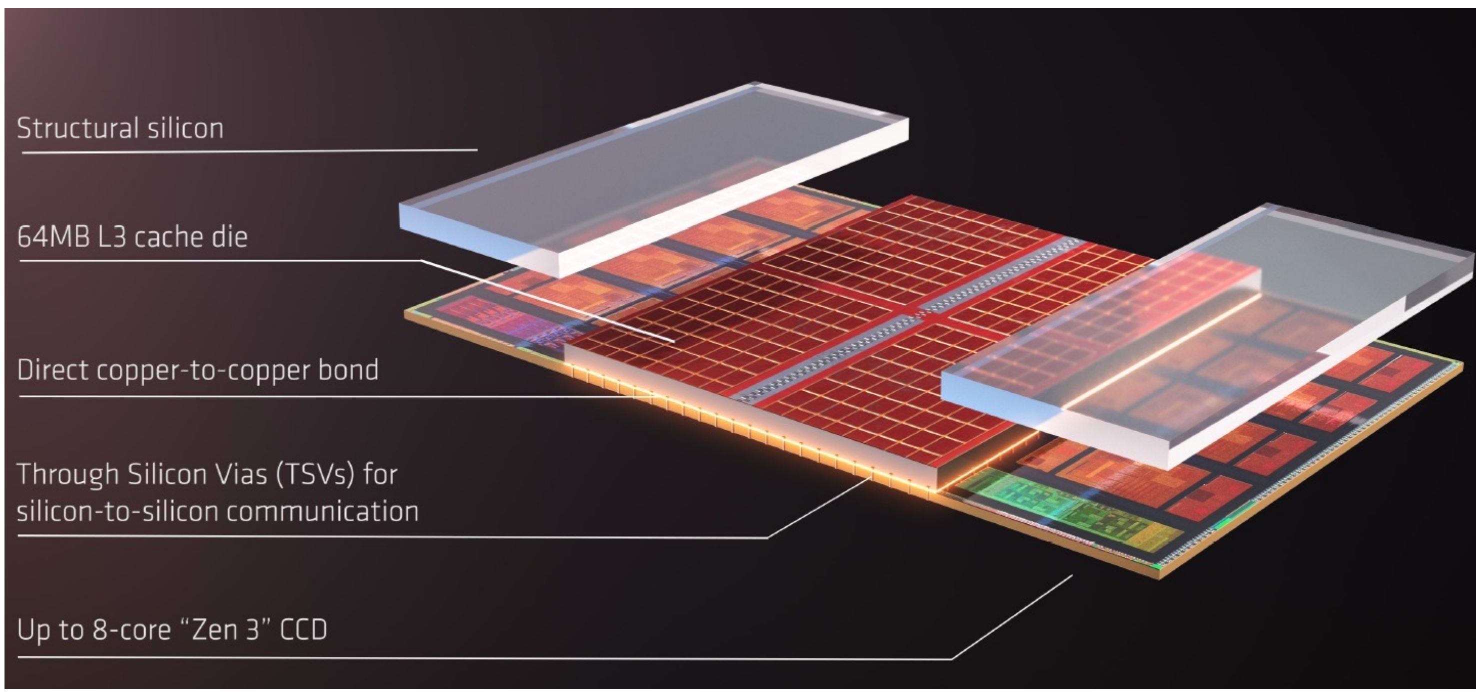
AMD’s 3D Last Level Cache (2021)



https://community.microcenter.com/discussion/5134/comparing-zen-3-to-zen-2

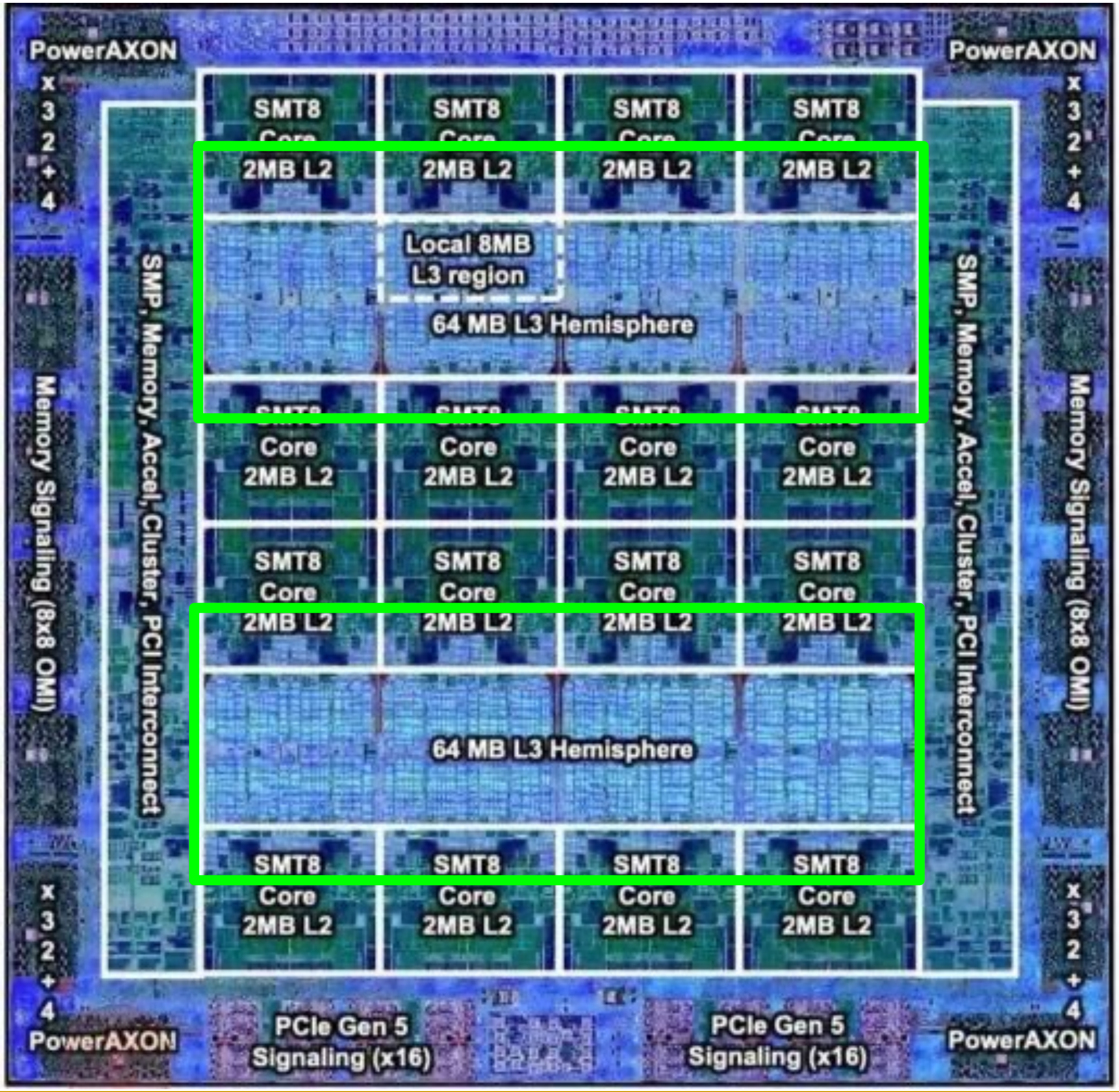
AMD increases the L3 size of their 8-core Zen 3 processors from 32 MB to 96 MB

Additional 64 MB L3 cache die stacked on top of the processor die
- Connected using Through Silicon Vias (TSVs)
- Total of 96 MB L3 cache



https://youtu.be/gqAYMx34euU
https://www.tech-critter.com/amd-keynote-computex-2021/

Deeper and Larger Memory Hierarchies



IBM POWER10, 2020

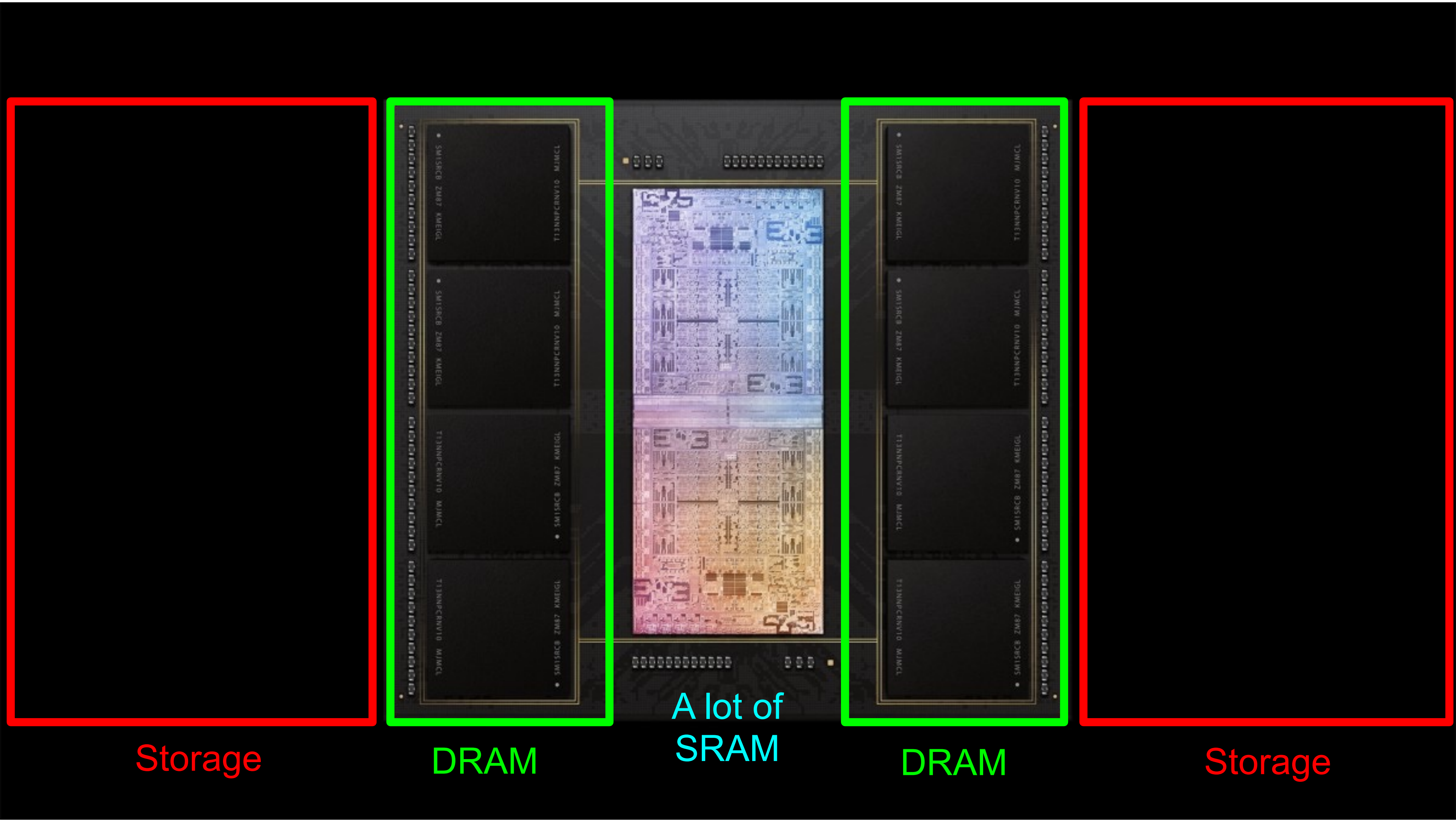
Cores:
15-16 cores,
8 threads/core

L2 Caches:
2 MB per core

L3 Cache:
120 MB shared

https://www.it-techblog.de/ibm-power10-prozessor-mehr-speicher-mehr-tempo-mehr-sicherheit/09/2020/

Deeper and Larger Memory Hierarchies



Apple M1 Ultra System (2022)

https://www.gsmarena.com/apple_announces_m1_ultra_with_20core_cpu_and_64core_gpu-news-53481.php

Data Movement Overwhelms Modern Machines

- Amirali Boroumand, Saugata Ghose, Youngsok Kim, Rachata Ausavarungnirun, Eric Shiu, Rahul Thakur, Daehyun Kim, Aki Kuusela, Allan Knies, Parthasarathy Ranganathan, and Onur Mutlu, **"Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks"** *Proceedings of the 23rd International Conference on Architectural Support for Programming Languages and Operating Systems* (***ASPLOS***), Williamsburg, VA, USA, March 2018.

62.7% of the total system energy is spent on data movement

Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks

Amirali Boroumand[1] Saugata Ghose[1] Youngsok Kim[2]
Rachata Ausavarungnirun[1] Eric Shiu[3] Rahul Thakur[3] Daehyun Kim[4,3]
Aki Kuusela[3] Allan Knies[3] Parthasarathy Ranganathan[3] Onur Mutlu[5,1]

Data Movement Overwhelms Accelerators

- Amirali Boroumand, Saugata Ghose, Berkin Akin, Ravi Narayanaswami, Geraldo F. Oliveira, Xiaoyu Ma, Eric Shiu, and Onur Mutlu,
  "Google Neural Network Models for Edge Devices: Analyzing and Mitigating Machine Learning Inference Bottlenecks"
  *Proceedings of the 30th International Conference on Parallel Architectures and Compilation Techniques (**PACT**)*, Virtual, September 2021.
  [Slides (pptx) (pdf)]
  [Talk Video (14 minutes)]

> 90% of the total system energy is spent on memory in large ML models

Google Neural Network Models for Edge Devices: Analyzing and Mitigating Machine Learning Inference Bottlenecks

Amirali Boroumand[†◇] Saugata Ghose[‡] Berkin Akin[§] Ravi Narayanaswami[§]
Geraldo F. Oliveira[⋆] Xiaoyu Ma[§] Eric Shiu[§] Onur Mutlu[⋆†]

[†]*Carnegie Mellon Univ.* [◇]*Stanford Univ.* [‡]*Univ. of Illinois Urbana-Champaign* [§]*Google* [⋆]*ETH Zürich*

The Problem

Data access is the major performance and energy bottleneck

Our current

design principles

cause great energy waste

(and great performance loss)

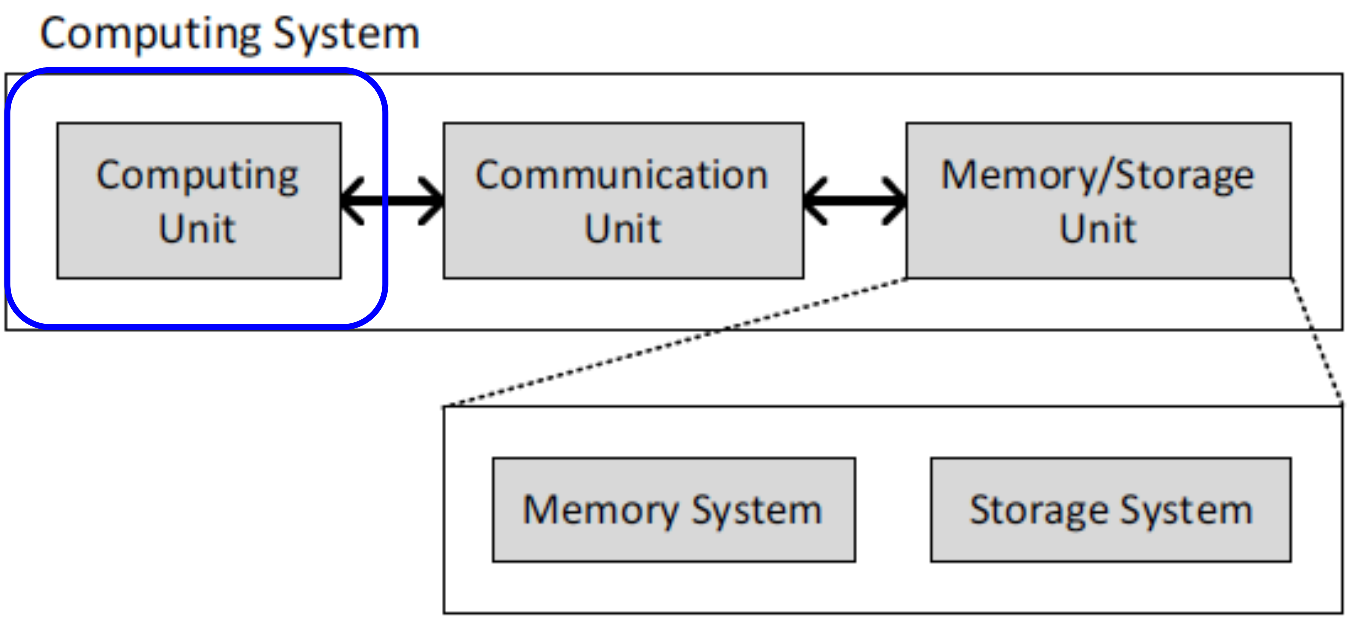
The Problem

Processing of data
is performed
far away from the data

Today's Computing Systems

- Processor centric

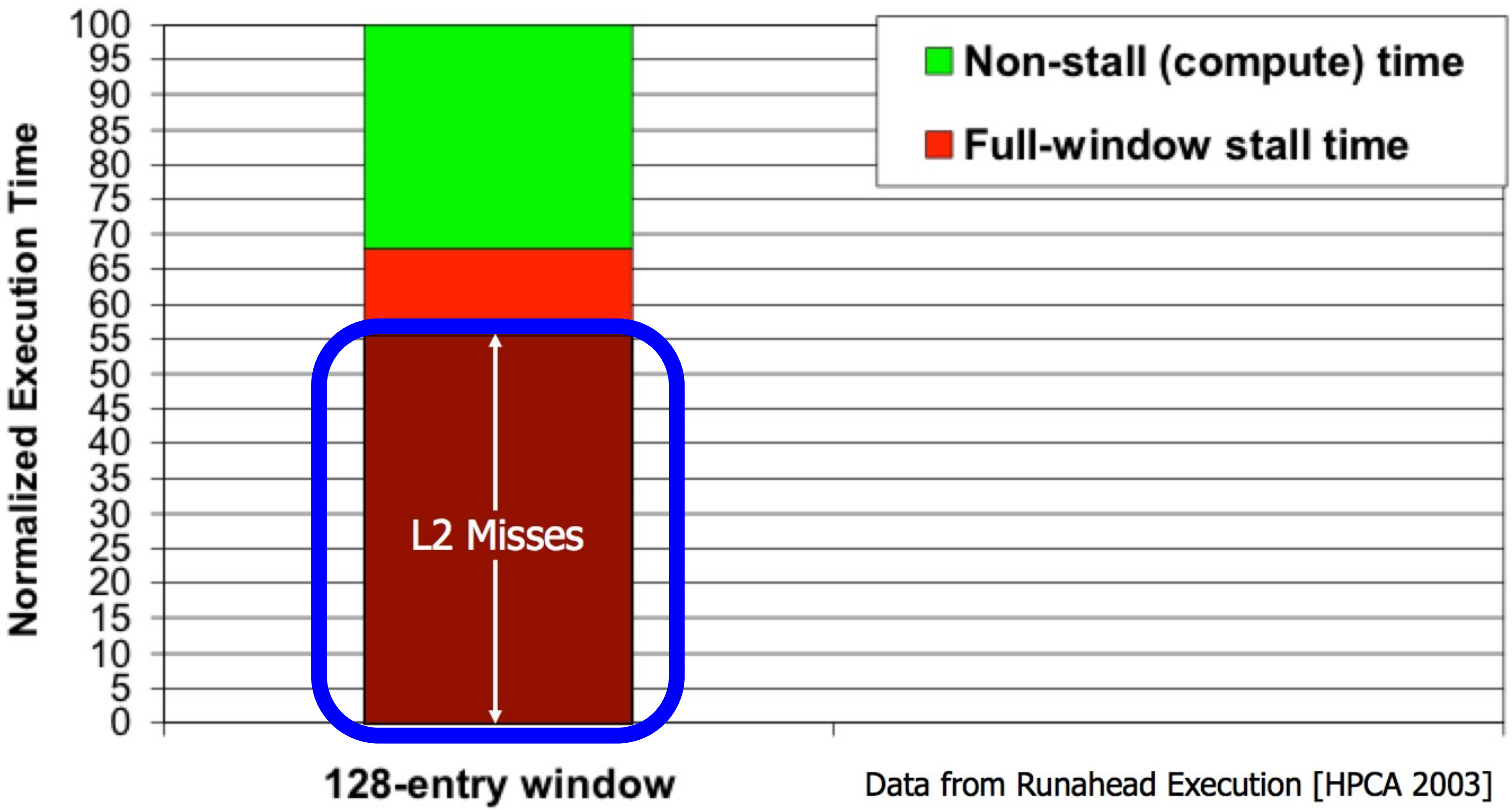
- All data processed in the processor → at great system cost



Yet …

I expect that over the coming decade memory subsystem design will be the *only* important design issue for microprocessors.

- "**It's the Memory, Stupid!**" (Richard Sites, MPR, 1996)



Data from Runahead Execution [HPCA 2003]

Mutlu+, "Runahead Execution: An Alternative to Very Large Instruction Windows for Out-of-Order Processors," HPCA 2003.

The Performance Perspective

- Onur Mutlu, Jared Stark, Chris Wilkerson, and Yale N. Patt,
  "Runahead Execution: An Alternative to Very Large Instruction Windows for Out-of-order Processors"
  Proceedings of the 9th International Symposium on High-Performance Computer Architecture (***HPCA***), pages 129-140, Anaheim, CA, February 2003. Slides (pdf)
  One of the 15 computer arch. papers of 2003 selected as Top Picks by IEEE Micro.
  HPCA Test of Time Award (awarded in 2021).

Runahead Execution: An Alternative to Very Large Instruction Windows for Out-of-order Processors

Onur Mutlu § Jared Stark † Chris Wilkerson ‡ Yale N. Patt §

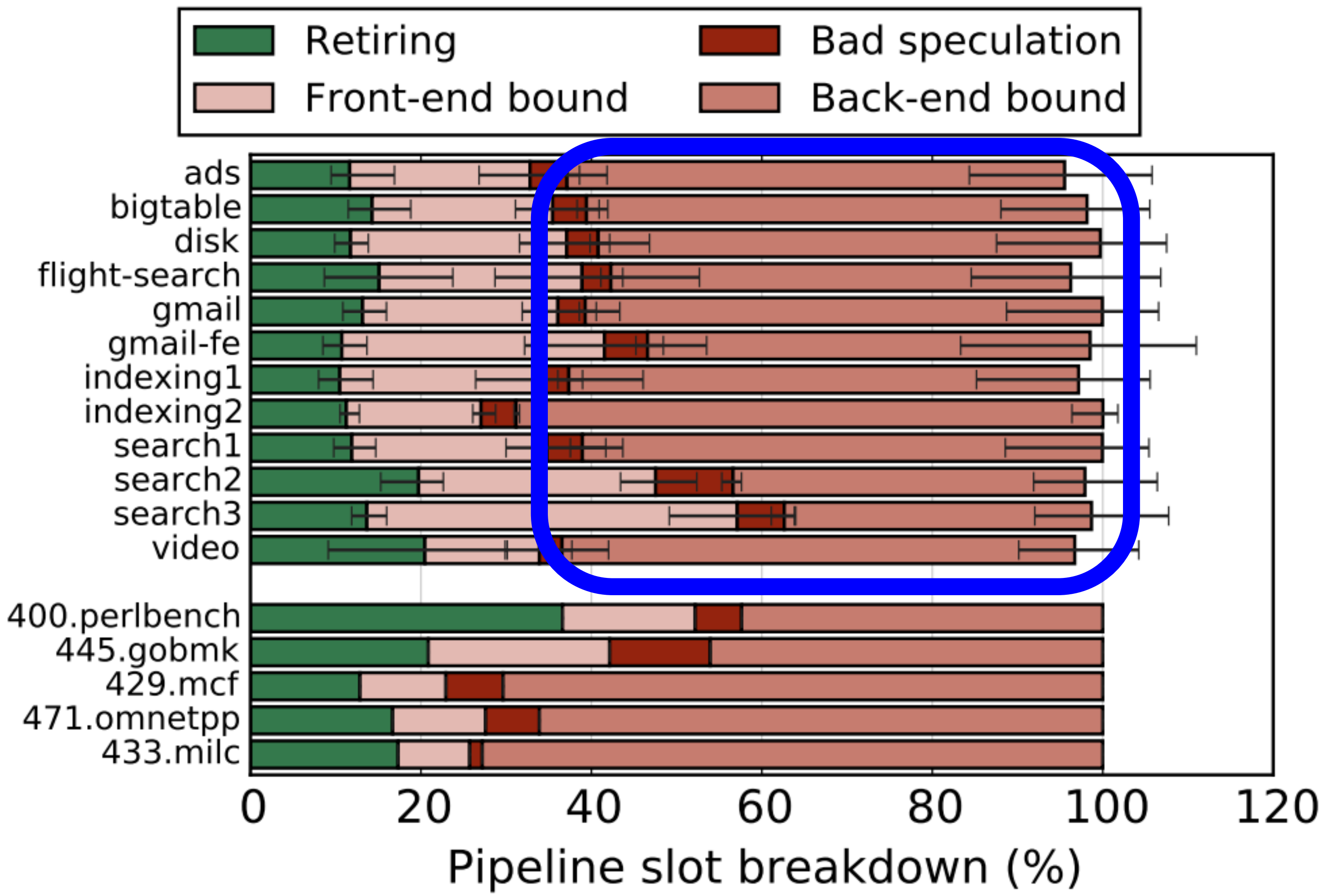
§ECE Department
The University of Texas at Austin
{onur,patt}@ece.utexas.edu

†Microprocessor Research
Intel Labs
jared.w.stark@intel.com

‡Desktop Platforms Group
Intel Corporation
chris.wilkerson@intel.com

The Performance Perspective (Today)

- All of Google's Data Center Workloads (2015):



Kanev+, "Profiling a Warehouse-Scale Computer," ISCA 2015.

The Performance Perspective (Today)

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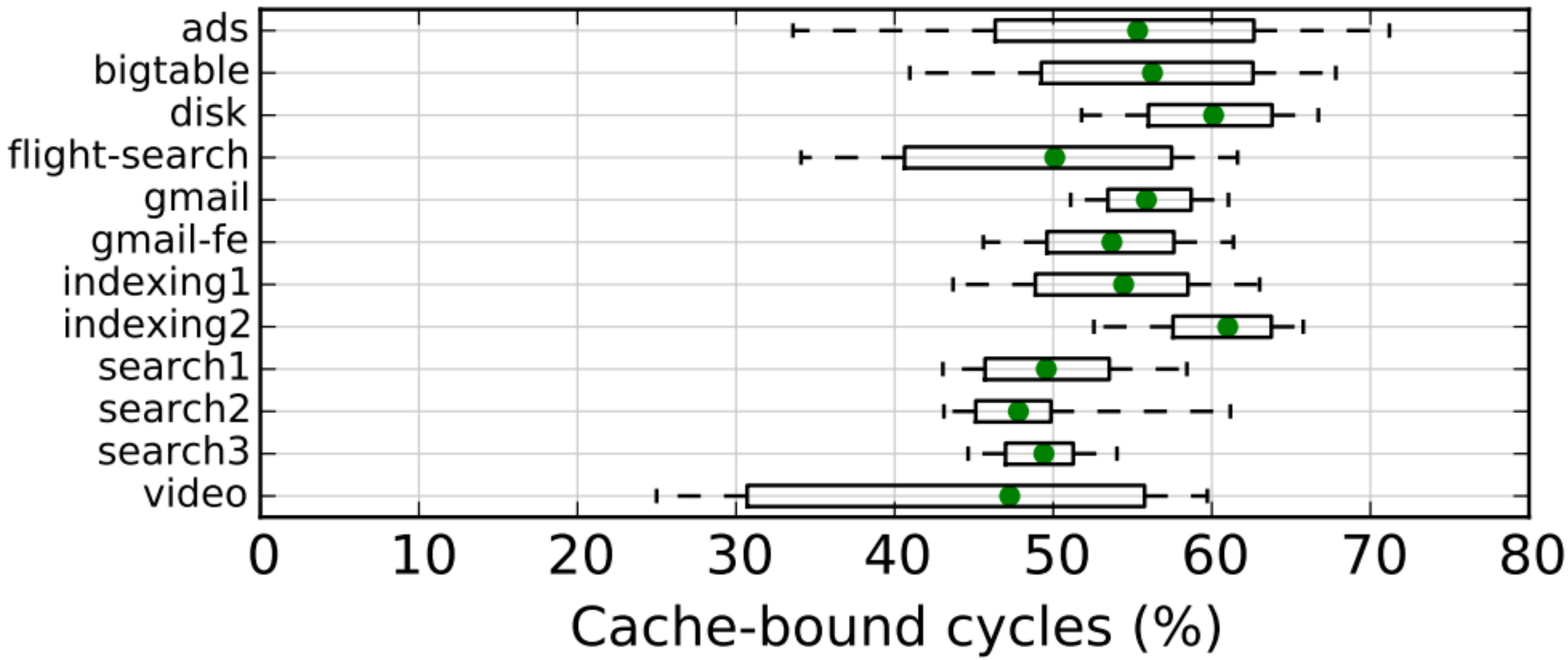


Figure 11: Half of cycles are spent stalled on caches.

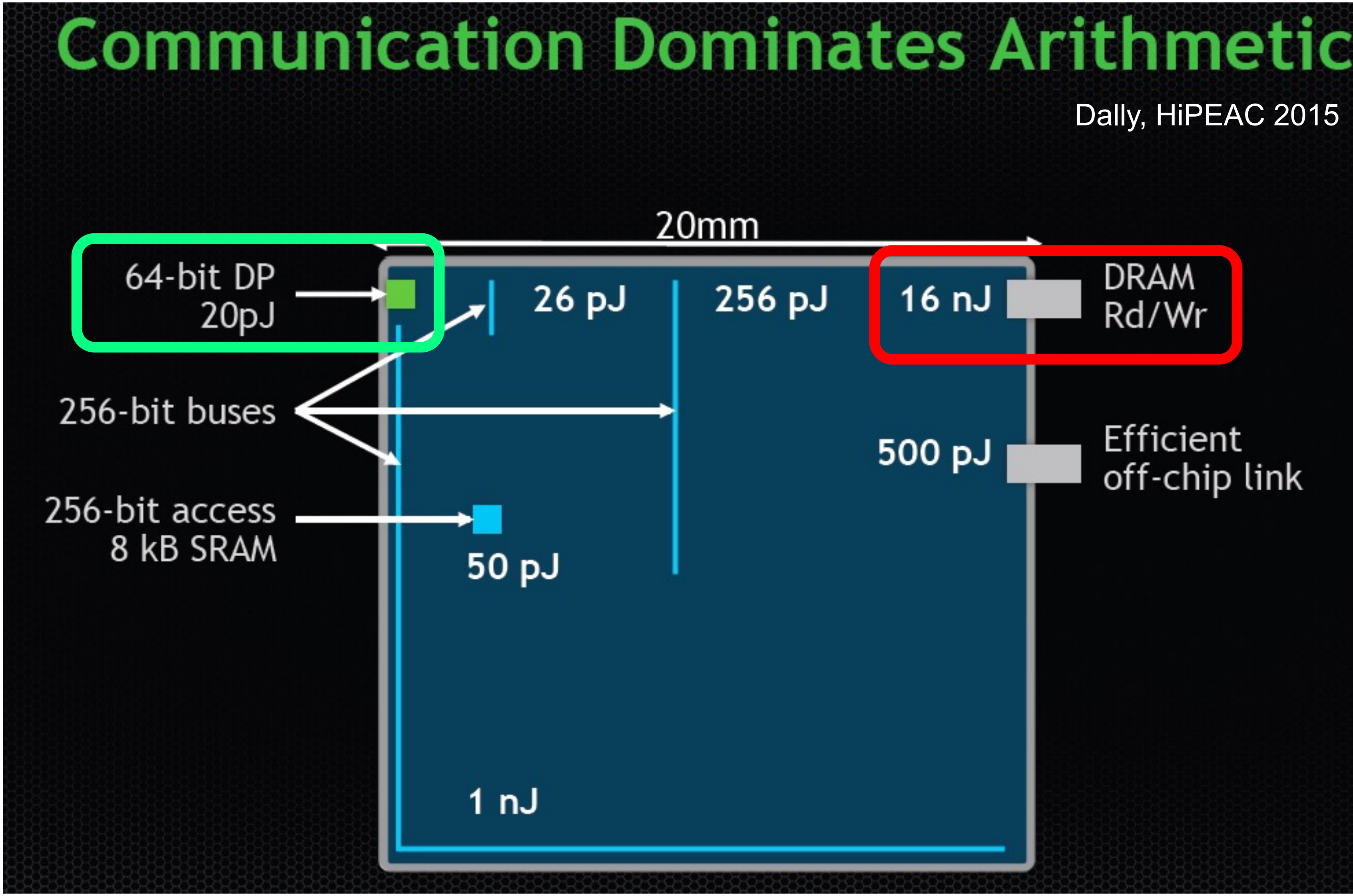
Kanev+, "Profiling a Warehouse-Scale Computer," ISCA 2015.

Perils of Processor-Centric Design

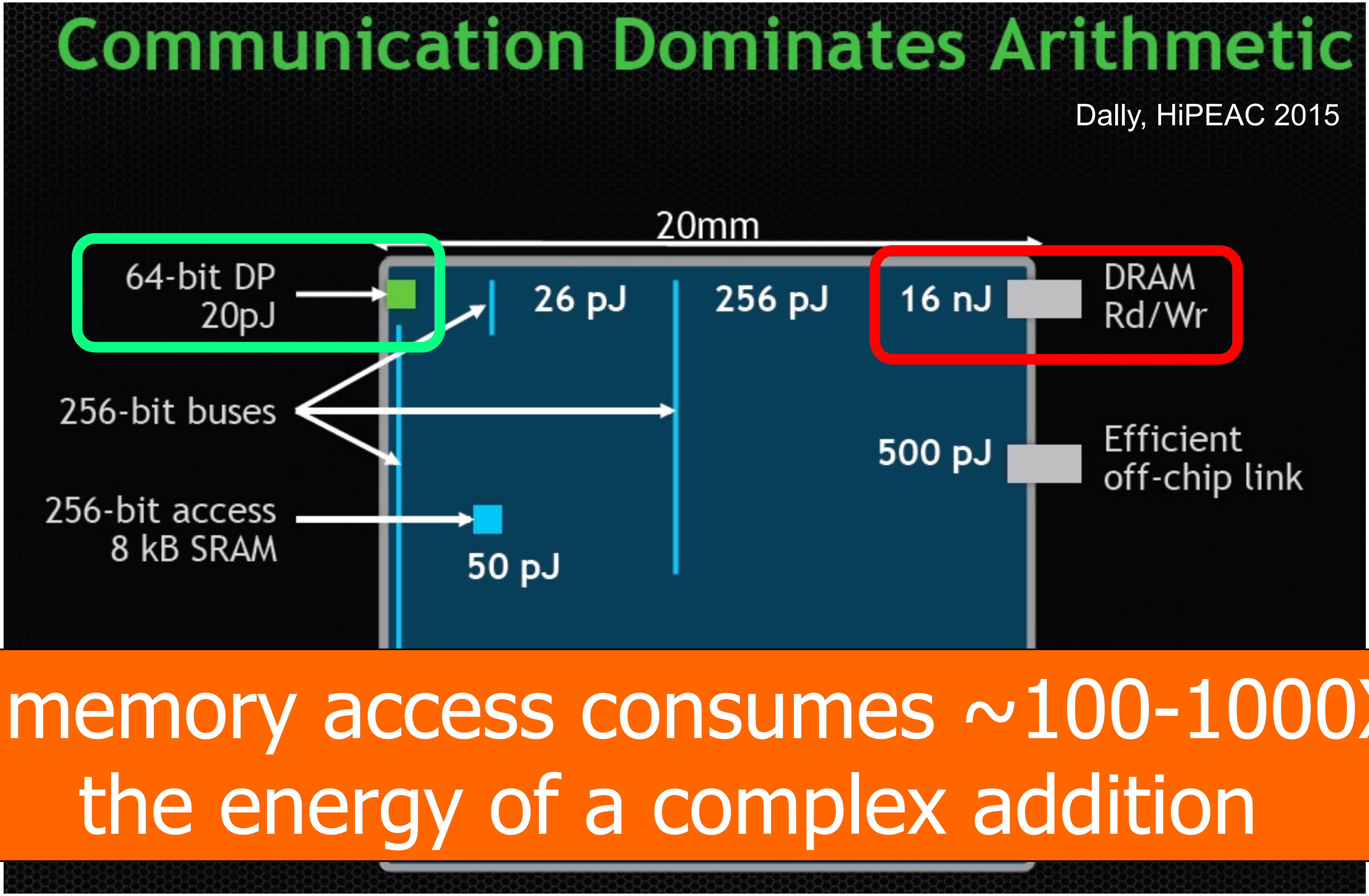
- Grossly-imbalanced systems
  - Processing done only in **one place**
  - All else just stores and moves data: **data moves a lot**
  - → Energy inefficient
  - → Low performance
  - → Complex

- Overly complex and bloated processor (and accelerators)
  - To tolerate data access from memory
  - Complex hierarchies and mechanisms
  - → Energy inefficient
  - → Low performance
  - → Complex

The Energy Perspective

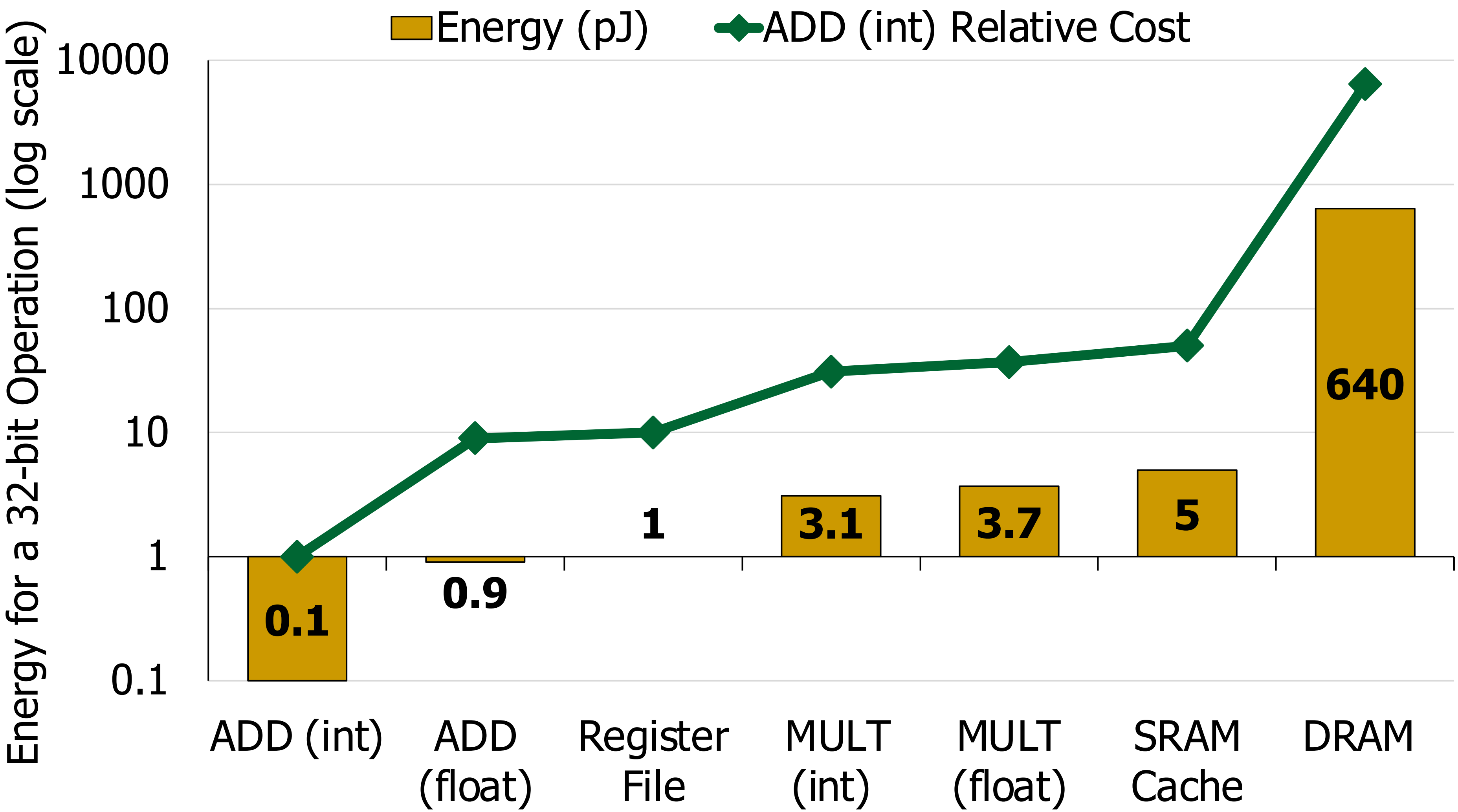


Data Movement vs. Computation Energy



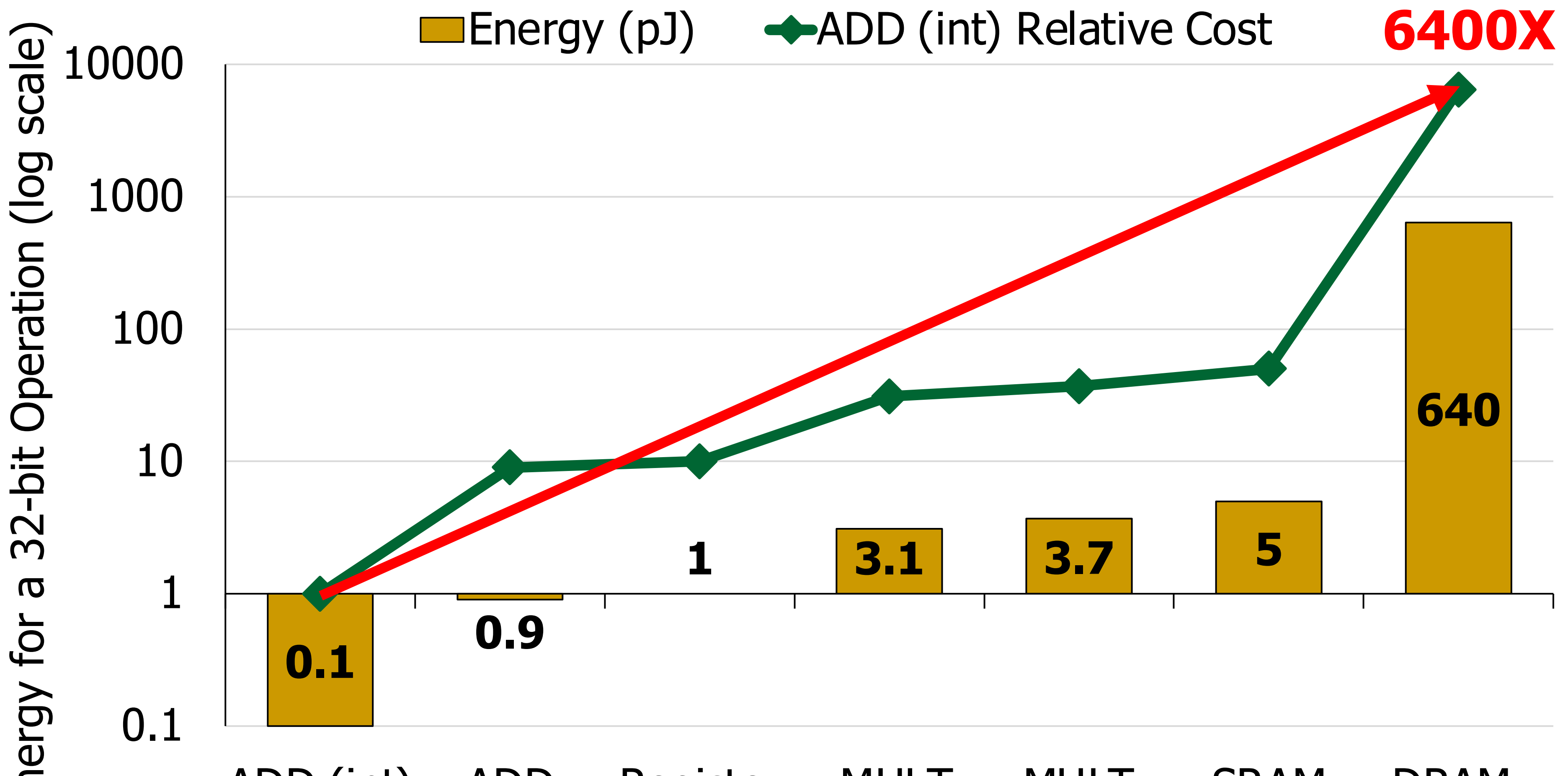
A memory access consumes ~100-1000X the energy of a complex addition

Data Movement vs. Computation Energy



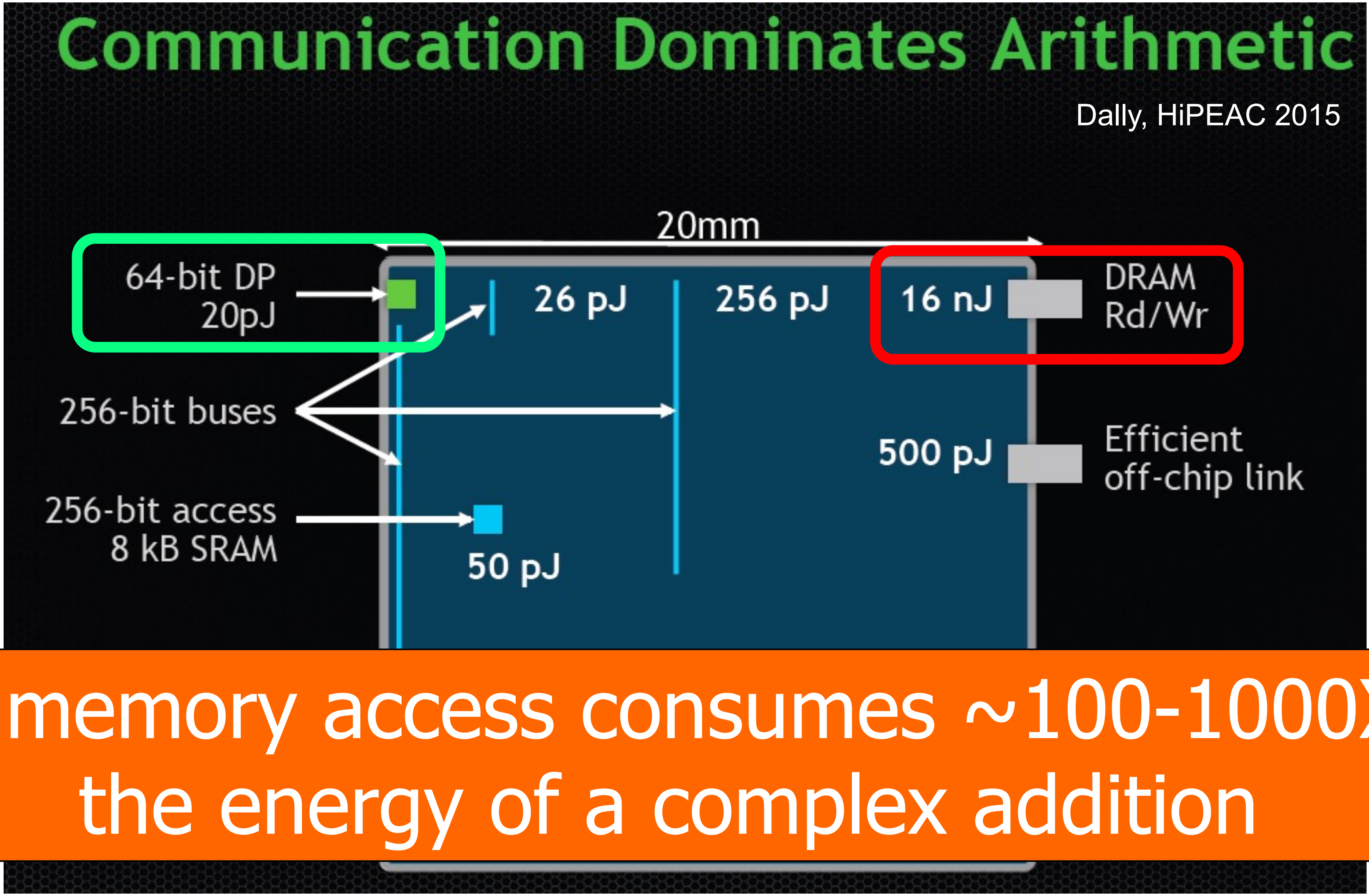
Han+, "EIE: Efficient Inference Engine on Compressed Deep Neural Network," ISCA 2016.

Data Movement vs. Computation Energy



A memory access consumes 6400X the energy of a simple integer addition

We Do Not Want to Move Data!



A memory access consumes ~100-1000X the energy of a complex addition

We Need A **Paradigm Shift** To …

- Enable computation with minimal data movement
- Compute where it makes sense (where data resides)
- Make computing architectures more data-centric

An Intelligent Architecture Handles Data Well

How to Handle Data Well

- **Ensure data does not overwhelm** the components
  - via intelligent algorithms
  - via intelligent architectures
  - via whole system designs: algorithm-architecture-devices

- **Take advantage of** vast amounts of **data** and metadata
  - to improve architectural & system-level decisions

- **Understand and exploit** properties of (different) **data**
  - to improve algorithms & architectures in various metrics

Corollaries: Computing Systems Today …

- Are processor-centric vs. **data-centric**

- Make designer-dictated decisions vs. **data-driven**

- Make component-based myopic decisions vs. **data-aware**

Architectures for Intelligent Machines

Data-centric

Data-driven

Data-aware

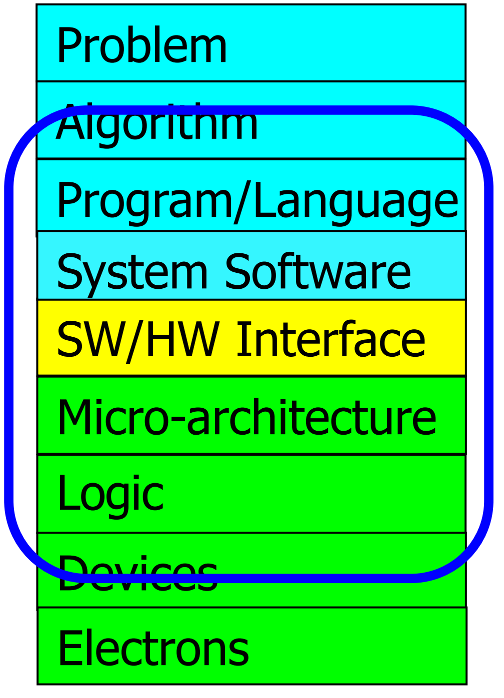
A Blueprint for Fundamentally Better Architectures

- Onur Mutlu,
  "Intelligent Architectures for Intelligent Computing Systems"
  Invited Paper in Proceedings of the Design, Automation, and Test in Europe Conference (***DATE***), Virtual, February 2021.
  [Slides (pptx) (pdf)]
  [IEDM Tutorial Slides (pptx) (pdf)]
  [Short DATE Talk Video (11 minutes)]
  [Longer IEDM Tutorial Video (1 hr 51 minutes)]

Intelligent Architectures for Intelligent Computing Systems

Onur Mutlu
ETH Zurich
omutlu@gmail.com

We Need to Revisit the Entire Stack



We can get there step by step

Data-Centric (Memory-Centric) Architectures

Data-Centric Architectures: Properties

- **Process data where it resides** (where it makes sense)
  - Processing in and near memory structures

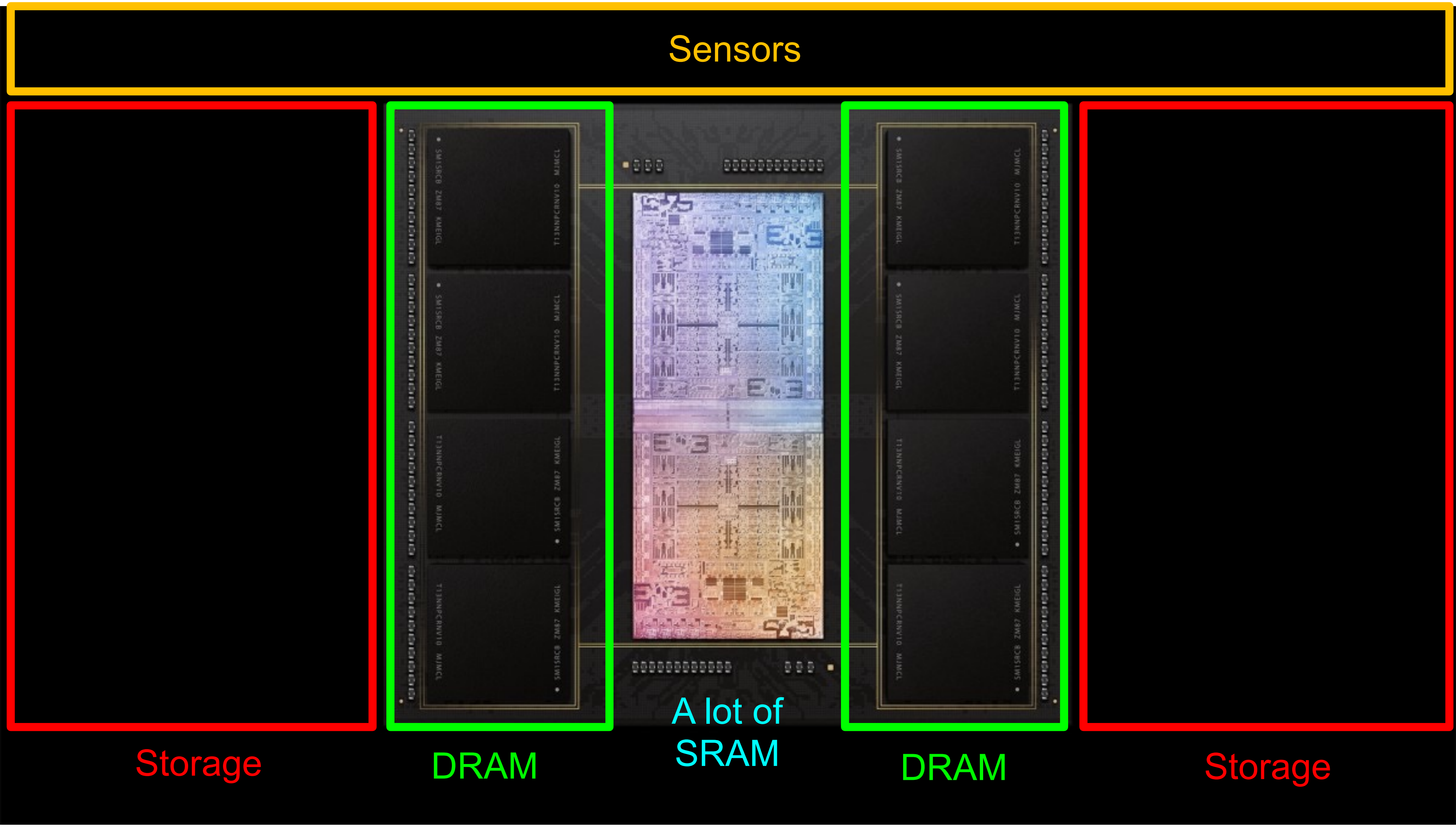
- **Low-latency and low-energy data access**
  - Low latency memory
  - Low energy memory

- **Low-cost data storage and processing**
  - High capacity memory at low cost: hybrid memory, compression

- **Intelligent data management**
  - Intelligent controllers handling robustness, security, cost, perf.

Processing Data Where It Makes Sense

Process Data Where It Makes Sense

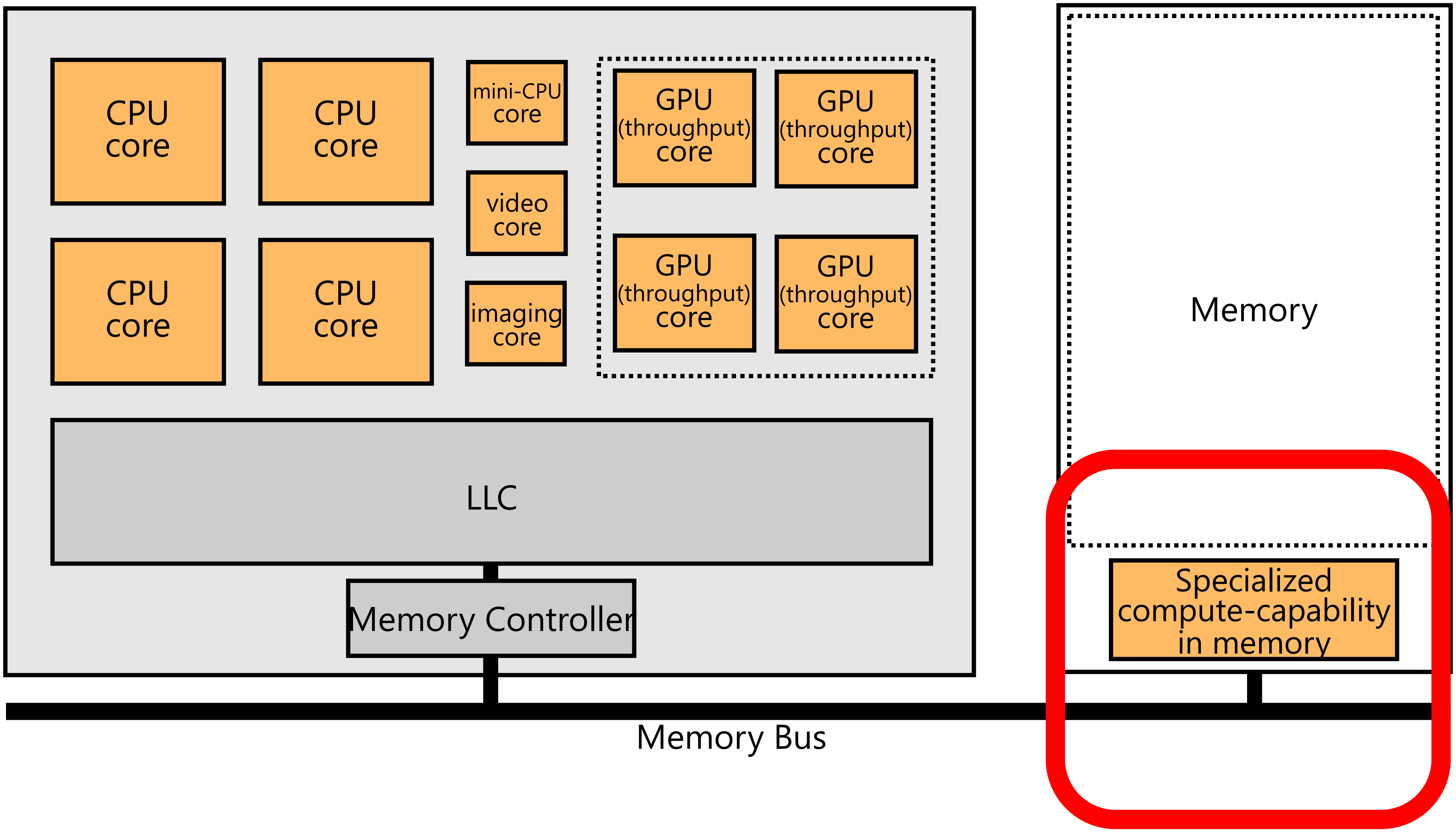


Apple M1 Ultra System (2022)

https://www.gsmarena.com/apple_announces_m1_ultra_with_20core_cpu_and_64core_gpu-news-53481.php

We Need to Think Differently from the Past Approaches

Mindset: Memory as an Accelerator



Memory similar to a "conventional" accelerator

Processing in Memory: An Old Idea (I)

- Kautz, "Cellular Logic-in-Memory Arrays", IEEE TC 1969.

IEEE TRANSACTIONS ON COMPUTERS, VOL. C-18, NO. 8, AUGUST 1969

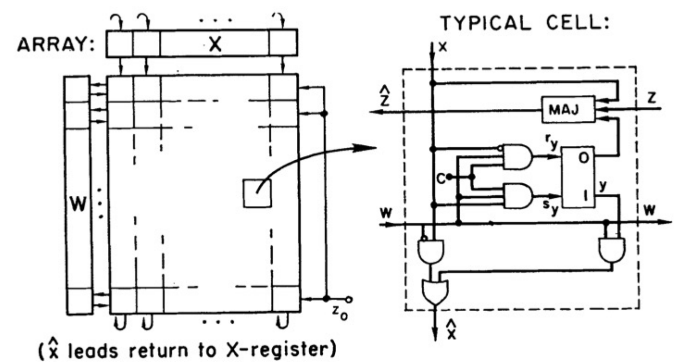
Cellular Logic-in-Memory Arrays

WILLIAM H. KAUTZ, MEMBER, IEEE

Abstract—As a direct consequence of large-scale integration, many advantages in the design, fabrication, testing, and use of digital circuitry can be achieved if the circuits can be arranged in a two-dimensional iterative, or cellular, array of identical elementary networks, or cells. When a small amount of storage is included in each cell, the same array may be regarded either as a logically enhanced memory array, or as a logic array whose elementary gates and connections can be "programmed" to realize a desired logical behavior.

In this paper the specific engineering features of such cellular logic-in-memory (CLIM) arrays are discussed, and one such special-purpose array, a cellular sorting array, is described in detail to illustrate how these features may be achieved in a particular design. It is shown how the cellular sorting array can be employed as a single-address, multiword memory that keeps in order all words stored within it. It can also be used as a content-addressed memory, a pushdown memory, a buffer memory, and (with a lower logical efficiency) a programmable array for the realization of arbitrary switching functions. A second version of a sorting array, operating on a different sorting principle, is also described.

Index Terms—Cellular logic, large-scale integration, logic arrays logic in memory, push-down memory, sorting, switching functions.



CELL EQUATIONS: $\hat{x} = \bar{w}x + wy$
$s_y = wcx,\ r_y = wc\bar{x}$
$\hat{z} = M(x, \bar{y}, z) = x\bar{y} + z(x + \bar{y})$

Fig. 1. Cellular sorting array I.

https://doi.org/10.1109/T-C.1969.222754

Processing in Memory: An Old Idea (II)

- Stone, "A Logic-in-Memory Computer," IEEE TC 1970.

A Logic-in-Memory Computer

HAROLD S. STONE

Abstract—If, as presently projected, the cost of microelectronic arrays in the future will tend to reflect the number of pins on the array rather than the number of gates, the logic-in-memory array is an extremely attractive computer component. Such an array is essentially a microelectronic memory with some combinational logic associated with each storage element.

Processing in Memory: An Old Idea (III)

- Patterson et al., "A Case for Intelligent RAM," IEEE Micro 1997.

A Case for Intelligent RAM

David Patterson

Thomas Anderson

Neal Cardwell

Richard Fromm

Kimberly Keeton

Christoforos Kozyrakis

Randi Thomas

Katherine Yelick

University of California, Berkeley

Two trends call into question the current practice of fabricating microprocessors and DRAMs as different chips on different fabrication lines. The gap between processor and DRAM speed is growing at 50% per year; and the size and organization of memory on a single DRAM chip is becoming awkward to use, yet size is growing at 60% per year.

Intelligent RAM, or IRAM, merges processing and memory into a single chip to lower memory latency, increase memory bandwidth, and improve energy efficiency. It also allows more flexible selection of memory size and organization, and promises savings in board area. This article reviews the state of microprocessors and DRAMs today, explores some of the opportunities and challenges for IRAMs, and finally estimates performance and energy efficiency of three IRAM designs.

puter designers can scale the number of memory chips independently of the number of processors. Most desktop systems have one processor and 4 to 32 DRAM chips, but most server systems have 2 to 16 processors and 32 to 256 DRAMs. Memory systems have standardized on single in-line memory module (SIMM) or dual in-line memory module (DIMM) packaging, which allow the end user to scale the amount of memory in a system.

Quantitative evidence of the industry's success is its size: In 1995, DRAMs were a $37-billion industry, and microprocessors were a $20-billion industry. In addition to financial success, the technologies of these industries have improved at unparalleled rates. DRAM capacity has quadrupled on average every three years since 1976, while microprocessor speed has done the same

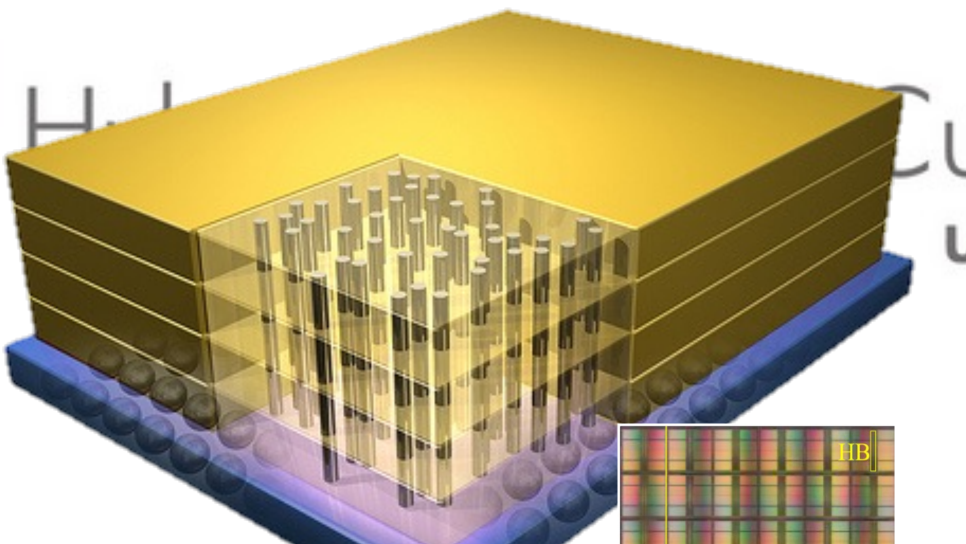
Why In-Memory Computation Today?

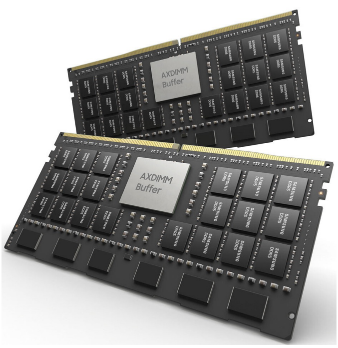
- **Huge problems with Memory Technology**
  - Memory technology scaling is not going well (e.g., RowHammer)
  - Many scaling issues demand intelligence in memory

- **Huge demand from Applications & Systems**
  - Data access bottleneck
  - Energy & power bottlenecks
  - Data movement energy dominates computation energy
  - Need all at the same time: performance, energy, sustainability
  - We can improve all metrics by minimizing data movement

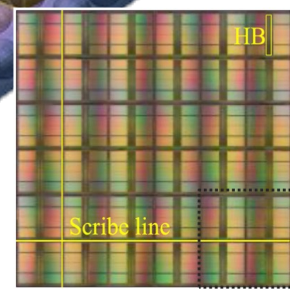
- **Designs are squeezed in the middle**

Processing-in-Memory Landscape Today

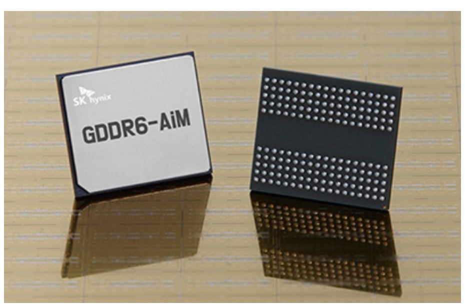




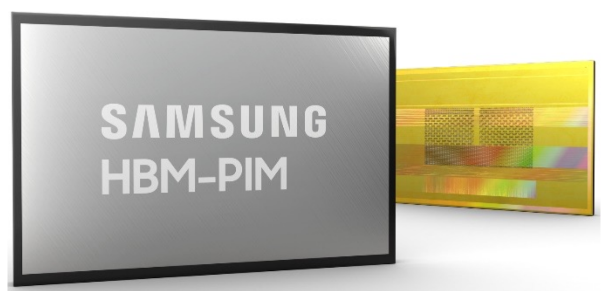
[Samsung 2021]



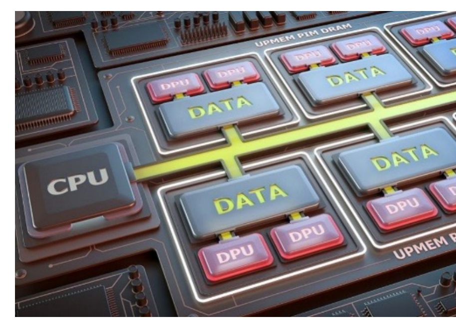
[Alibaba 2022]



[SK Hynix 2022]



[Samsung 2021]



[UPMEM 2019]

And, many other experimental chips and startups

Memory Scaling Issues **Are** Real

- Onur Mutlu,
  "Memory Scaling: A Systems Architecture Perspective"
  *Proceedings of the 5th International Memory Workshop (**IMW**)*, Monterey, CA, May 2013. Slides (pptx) (pdf)
  EETimes Reprint

Memory Scaling: A Systems Architecture Perspective

Onur Mutlu
Carnegie Mellon University
onur@cmu.edu
http://users.ece.cmu.edu/~omutlu/

https://people.inf.ethz.ch/omutlu/pub/memory-scaling_memcon13.pdf

A Curious Phenomenon **[Kim et al., ISCA 2014]**

One can

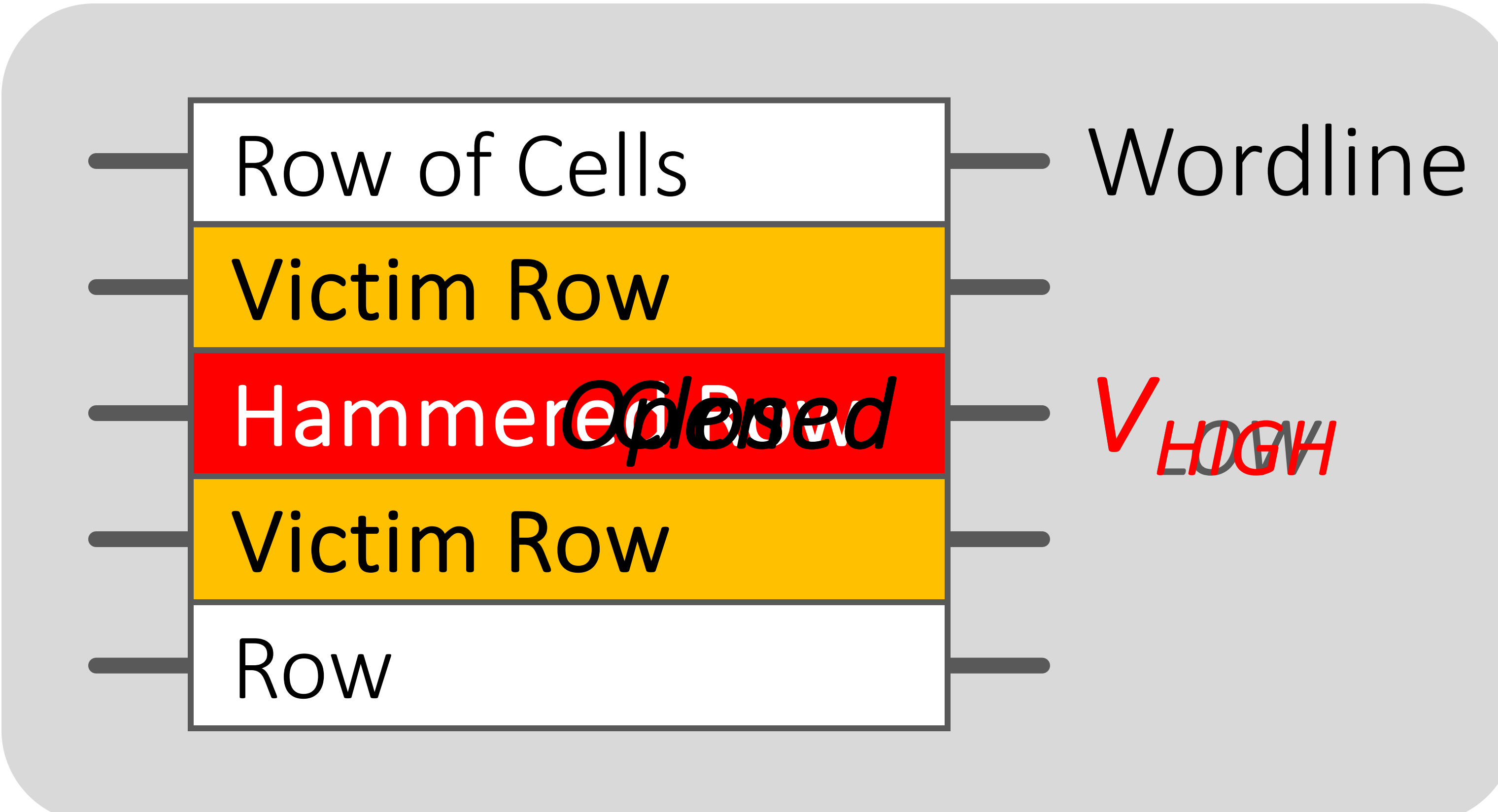
predictably induce errors

in most DRAM memory chips

Kim+, "Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors," ISCA 2014.


Rowhammer

Modern Memory is Prone to Disturbance Errors



Repeatedly reading a row enough times (before memory gets refreshed) induces disturbance errors in **adjacent rows** in most real DRAM chips you can buy today

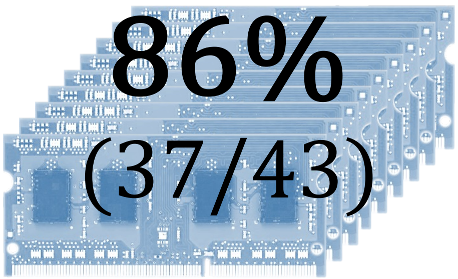
Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors, (Kim et al., ISCA 2014)

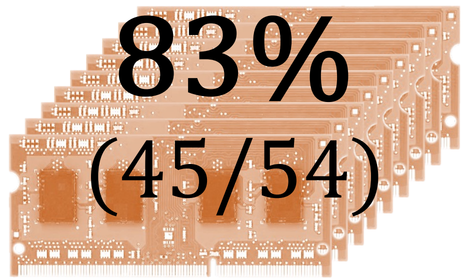
Most DRAM Modules Are Vulnerable

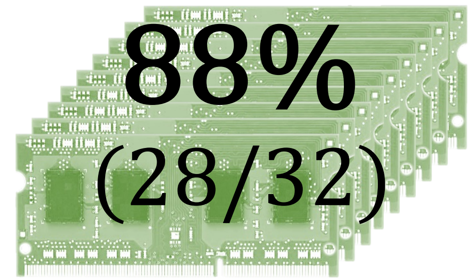
A company

B company

C company







A company: Up to 1.0×10^7 errors

B company: Up to 2.7×10^6 errors

C company: Up to 3.3×10^5 errors

Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors, (Kim et al., ISCA 2014)

The RowHammer Vulnerability

A simple hardware failure mechanism
can create a widespread
system security vulnerability

WIRED

Forget Software—Now Hackers Are Exploiting Physics

BUSINESS | CULTURE | DESIGN | GEAR | SCIENCE

SHARE

SHARE 18276

TWEET

ANDY GREENBERG SECURITY 08.31.16 7:00 AM

FORGET SOFTWARE—NOW HACKERS ARE EXPLOITING PHYSICS

RowHammer [ISCA 2014]

- Yoongu Kim, Ross Daly, Jeremie Kim, Chris Fallin, Ji Hye Lee, Donghyuk Lee, Chris Wilkerson, Konrad Lai, and Onur Mutlu,
  "Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors"
  *Proceedings of the 41st International Symposium on Computer Architecture (**ISCA**)*, Minneapolis, MN, June 2014.
  [Slides (pptx) (pdf)] [Lightning Session Slides (pptx) (pdf)] [Source Code and Data] [Lecture Video (1 hr 49 mins), 25 September 2020]
  One of the 7 papers of 2012-2017 selected as Top Picks in Hardware and Embedded Security for IEEE TCAD (link).
  Selected to the ISCA-50 25-Year Retrospective Issue covering 1996-2020 in 2023 (Retrospective (pdf) Full Issue).

Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors

Yoongu Kim[1] Ross Daly* Jeremie Kim[1] Chris Fallin* Ji Hye Lee[1]
Donghyuk Lee[1] Chris Wilkerson[2] Konrad Lai Onur Mutlu[1]

[1]Carnegie Mellon University [2]Intel Labs

Memory Scaling Issues **Are** Real

- Onur Mutlu and Jeremie Kim,
  "RowHammer: A Retrospective"
  *IEEE Transactions on Computer-Aided Design of Integrated Circuits and Systems (**TCAD**) Special Issue on Top Picks in Hardware and Embedded Security*, 2019.
  [Preliminary arXiv version]
  [Slides from COSADE 2019 (pptx)]
  [Slides from VLSI-SOC 2020 (pptx) (pdf)]
  [Talk Video (1 hr 15 minutes, with Q&A)]

RowHammer: A Retrospective

Onur Mutlu[§‡] Jeremie S. Kim[‡§]
[§]ETH Zürich [‡]Carnegie Mellon University

Memory Scaling Issues **Are** Real

- Onur Mutlu, Ataberk Olgun, and A. Giray Yaglikci,
  "Fundamentally Understanding and Solving RowHammer"
  *Invited Special Session Paper at the 28th Asia and South Pacific Design Automation Conference (**ASP-DAC**)*, Tokyo, Japan, January 2023.
  [arXiv version]
  [Slides (pptx) (pdf)]
  [Talk Video (26 minutes)]

Fundamentally Understanding and Solving RowHammer

Onur Mutlu
onur.mutlu@safari.ethz.ch
ETH Zürich
Zürich, Switzerland

Ataberk Olgun
ataberk.olgun@safari.ethz.ch
ETH Zürich
Zürich, Switzerland

A. Giray Yağlıkcı
giray.yaglikci@safari.ethz.ch
ETH Zürich
Zürich, Switzerland

https://arxiv.org/pdf/2211.07613.pdf

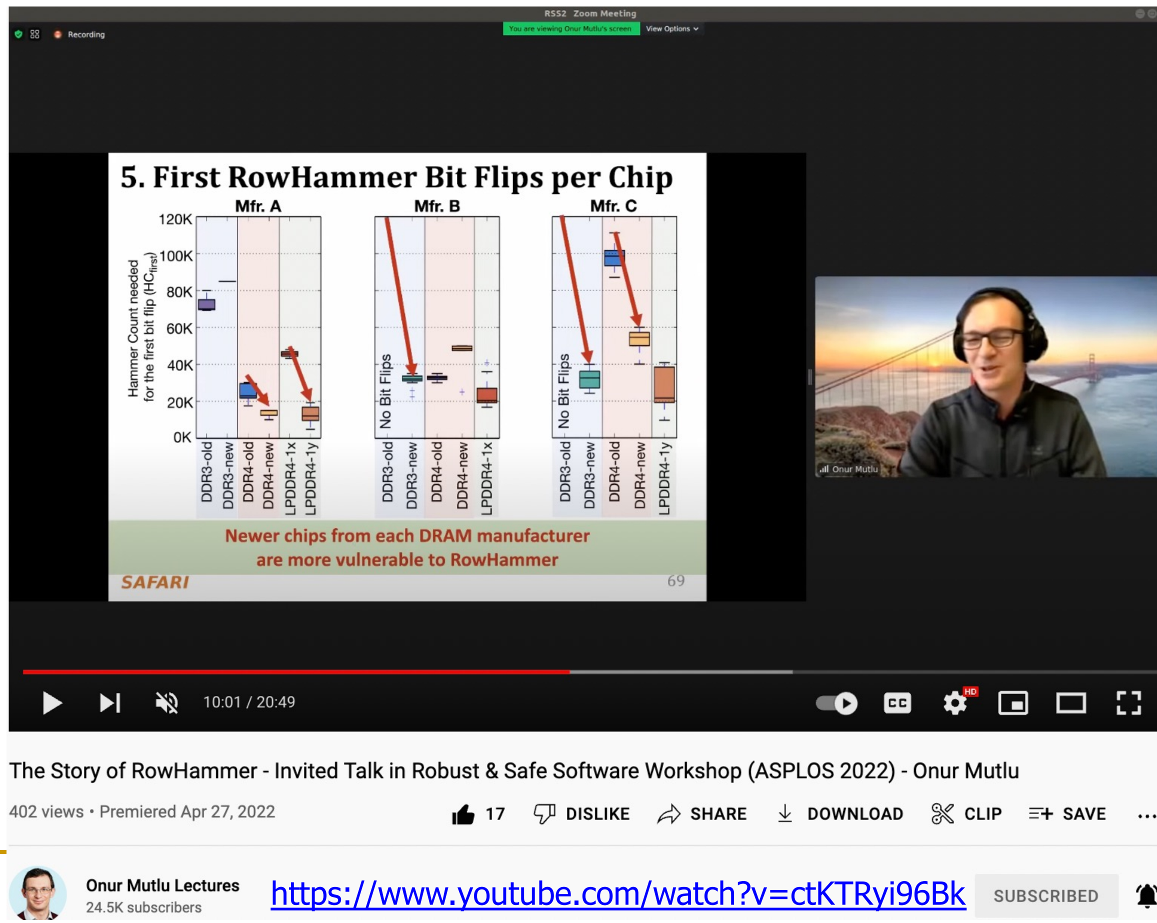
The Story of RowHammer Tutorial …

Onur Mutlu,
"Security Aspects of DRAM: The Story of RowHammer"
*Invited Tutorial at 14th IEEE Electron Devices Society International Memory Workshop (**IMW**)*, Dresden, Germany, May 2022.
[Slides (pptx)(pdf)]
[Tutorial Video (57 minutes)]

https://www.youtube.com/watch?v=37hWglkQRG0

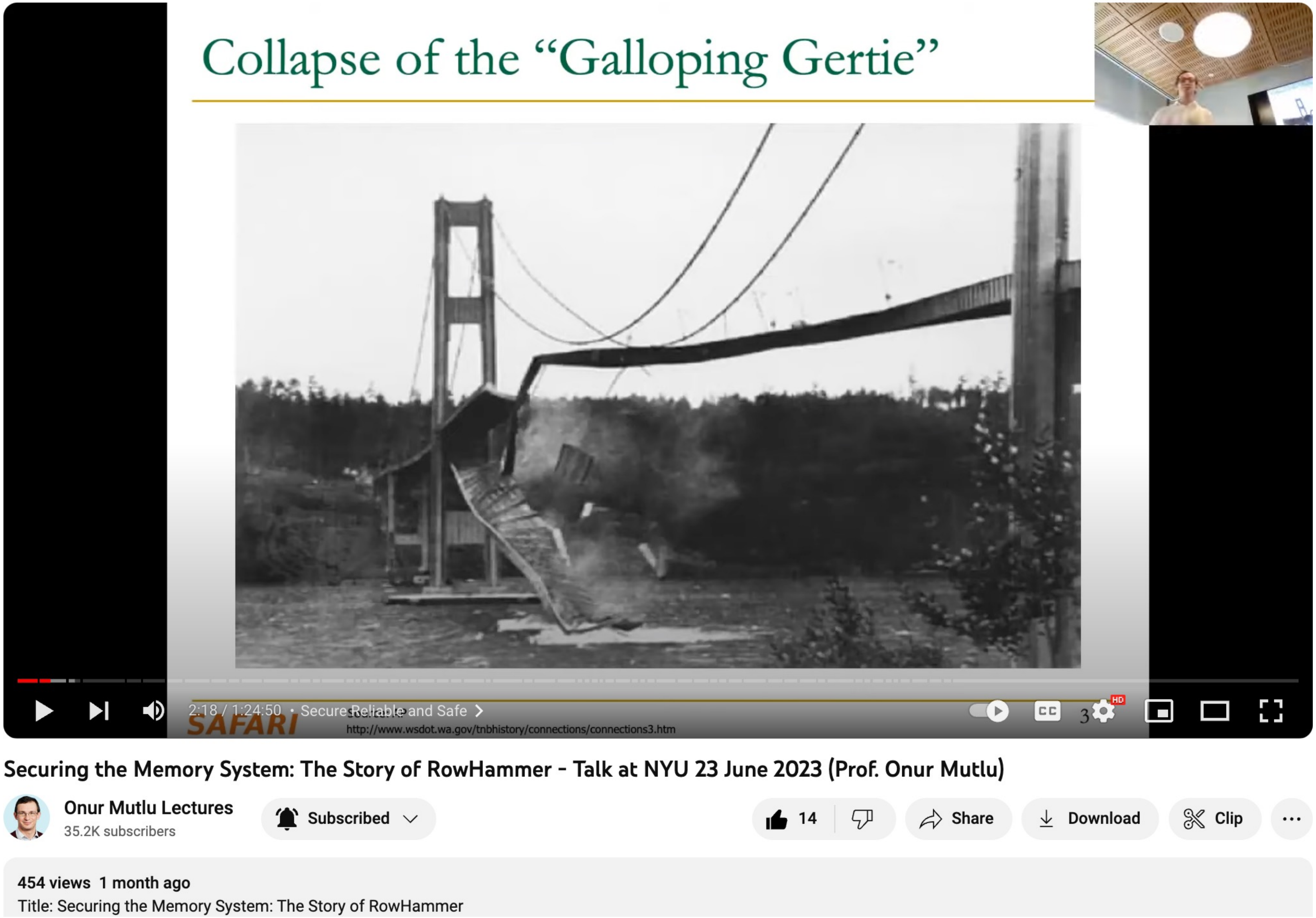
10 Years of RowHammer in 20 Minutes

- Onur Mutlu,
  ["The Story of RowHammer"]
  *Invited Talk at the Workshop on Robust and Safe Software 2.0 (**RSS2**)*, held with *the 27th International Conference on Architectural Support for Programming Languages and Operating Systems* (***ASPLOS***), Virtual, 28 February 2022.
  [Slides (pptx) (pdf)]



https://www.youtube.com/watch?v=ctKTRyi96Bk

Latest RowHammer Lecture



https://www.youtube.com/watch?v=p1pjF8WvERQ

The Push from Circuits and Devices

Main Memory Needs

Intelligent Controllers

An Example Intelligent Controller

- A. Giray Yaglikci, Minesh Patel, Jeremie S. Kim, Roknoddin Azizi, Ataberk Olgun, Lois Orosa, Hasan Hassan, Jisung Park, Konstantinos Kanellopoulos, Taha Shahroodi, Saugata Ghose, and Onur Mutlu,
  "BlockHammer: Preventing RowHammer at Low Cost by Blacklisting Rapidly-Accessed DRAM Rows"
  *Proceedings of the 27th International Symposium on High-Performance Computer Architecture (**HPCA**)*, Virtual, February-March 2021.
  [Slides (pptx) (pdf)]
  [Short Talk Slides (pptx) (pdf)]
  [Intel Hardware Security Academic Awards Short Talk Slides (pptx) (pdf)]
  [Talk Video (22 minutes)]
  [Short Talk Video (7 minutes)]
  [Intel Hardware Security Academic Awards Short Talk Video (2 minutes)]
  [BlockHammer Source Code]
  Intel Hardware Security Academic Award Finalist (one of 4 finalists out of 34 nominations)

BlockHammer: Preventing RowHammer at Low Cost by Blacklisting Rapidly-Accessed DRAM Rows

A. Giray Yağlıkçı[1] Minesh Patel[1] Jeremie S. Kim[1] Roknoddin Azizi[1] Ataberk Olgun[1] Lois Orosa[1]
Hasan Hassan[1] Jisung Park[1] Konstantinos Kanellopoulos[1] Taha Shahroodi[1] Saugata Ghose[2] Onur Mutlu[1]
[1]*ETH Zürich* [2]*University of Illinois at Urbana–Champaign*

Industry's Intelligent DRAM Controllers (I)

ISSCC 2023 / SESSION 28 / HIGH-DENSITY MEMORIES /

28.8 A 1.1V 16Gb DDR5 DRAM with Probabilistic-Aggressor Tracking, Refresh-Management Functionality, Per-Row Hammer Tracking, a Multi-Step Precharge, and Core-Bias Modulation for Security and Reliability Enhancement

Woongrae Kim, Chulmoon Jung, Seongnyuh Yoo, Duckhwa Hong, Jeongjin Hwang, Jungmin Yoon, Ohyong Jung, Joonwoo Choi, Sanga Hyun, Mankeun Kang, Sangho Lee, Dohong Kim, Sanghyun Ku, Donhyun Choi, Nogeun Joo, Sangwoo Yoon, Junseok Noh, Byeongyong Go, Cheolhoe Kim, Sunil Hwang, Mihyun Hwang, Seol-Min Yi, Hyungmin Kim, Sanghyuk Heo, Yeonsu Jang, Kyoungchul Jang, Shinho Chu, Yoonna Oh, Kwidong Kim, Junghyun Kim, Soohwan Kim, Jeongtae Hwang, Sangil Park, Junphyo Lee, Inchul Jeong, Joohwan Cho, Jonghwan Kim

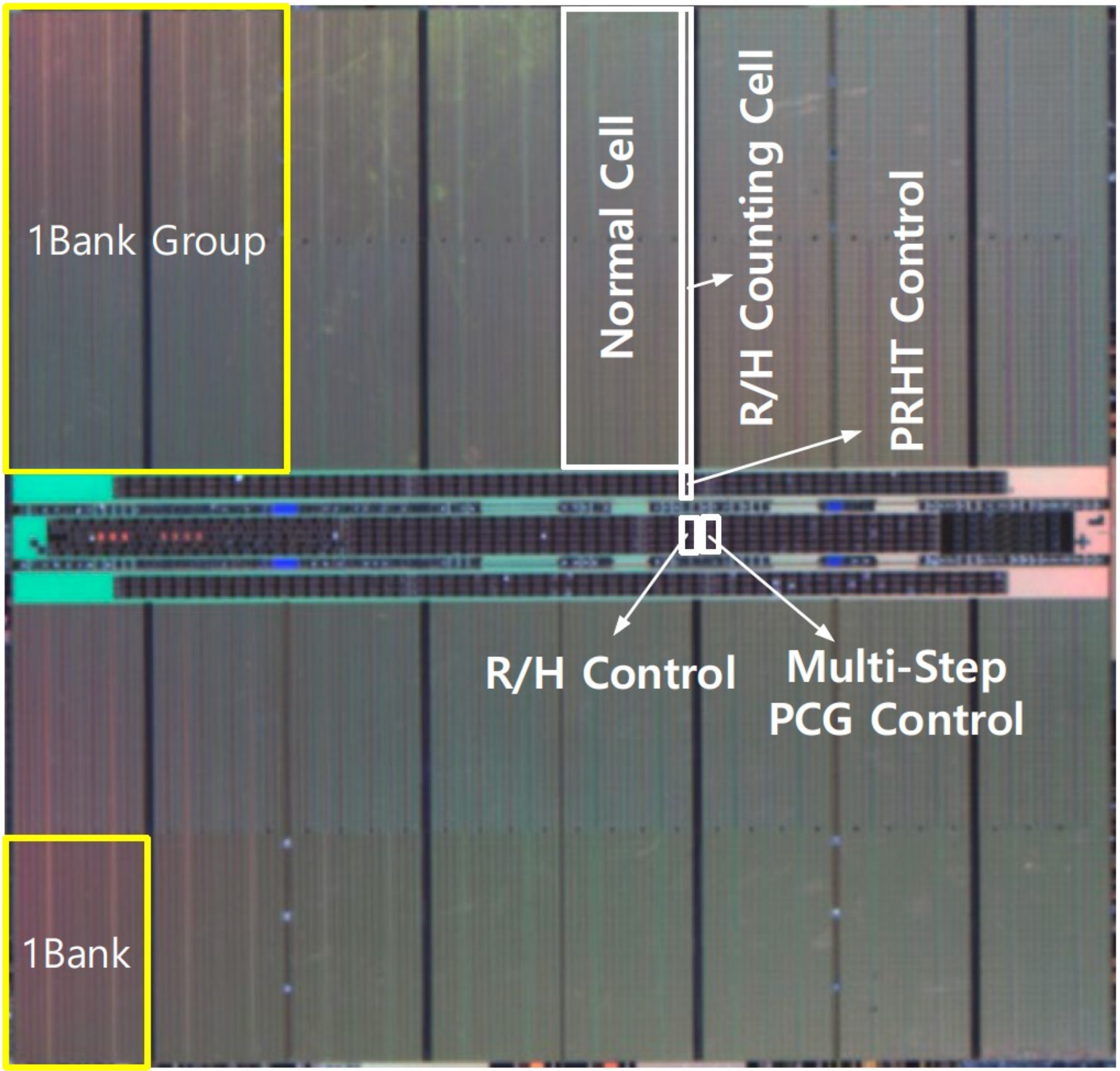
SK hynix Semiconductor, Icheon, Korea

Industry's Intelligent DRAM Controllers (II)

SK hynix Semiconductor, Icheon, Korea

DRAM products have been recently adopted in a wide range of high-performance computing applications: such as in cloud computing, in big data systems, and IoT devices. This demand creates larger memory capacity requirements, thereby requiring aggressive DRAM technology node scaling to reduce the cost per bit [1,2]. However, DRAM manufacturers are facing technology scaling challenges due to row hammer and refresh retention time beyond 1a-nm [2]. Row hammer is a failure mechanism, where repeatedly activating a DRAM row disturbs data in adjacent rows. Scaling down severely threatens reliability since a reduction of DRAM cell size leads to a reduction in the intrinsic row hammer tolerance [2,3]. To improve row hammer tolerance, there is a need to probabilistically activate adjacent rows with carefully sampled active addresses and to improve intrinsic row hammer tolerance [2]. In this paper, row-hammer-protection and refresh-management schemes are presented to guarantee DRAM security and reliability despite the aggressive scaling from 1a-nm to sub 10-nm nodes. The probabilistic-aggressor-tracking scheme with a refresh-management function (RFM) and per-row hammer tracking (PRHT) improve DRAM resilience. A multi-step precharge reinforces intrinsic row-hammer tolerance and a core-bias modulation improves retention time: even in the face of cell-transistor degradation due to technology scaling. This comprehensive scheme leads to a reduced probability of failure, due to row hammer attacks, by 93.1% and an improvement in retention time by 17%.

Industry's Intelligent DRAM Controllers (III)



ISSCC 2023 / SESSION 28 / HIGH-DENSITY MEMORIES /

28.8 A 1.1V 16Gb DDR5 DRAM with Probabilistic-Aggressor Tracking, Refresh-Management Functionality, Per-Row Hammer Tracking, a Multi-Step Precharge, and Core-Bias Modulation for Security and Reliability Enhancement

Woongrae Kim, Chulmoon Jung, Seongnyuh Yoo, Duckhwa Hong, Jeongjin Hwang, Jungmin Yoon, Ohyong Jung, Joonwoo Choi, Sanga Hyun, Mankeun Kang, Sangho Lee, Dohong Kim, Sanghyun Ku, Donhyun Choi, Nogeun Joo, Sangwoo Yoon, Junseok Noh, Byeongyong Go, Cheolhoe Kim, Sunil Hwang, Mihyun Hwang, Seol-Min Yi, Hyungmin Kim, Sanghyuk Heo, Yeonsu Jang, Kyoungchul Jang, Shinho Chu, Yoonna Oh, Kwidong Kim, Junghyun Kim, Soohwan Kim, Jeongtae Hwang, Sangil Park, Junphyo Lee, Inchul Jeong, Joohwan Cho, Jonghwan Kim

SK hynix Semiconductor, Icheon, Korea

Industry's Intelligent DRAM Controllers (IV)

DSAC: Low-Cost Rowhammer Mitigation Using In-DRAM Stochastic and Approximate Counting Algorithm

Seungki Hong Dongha Kim Jaehyung Lee Reum Oh
Changsik Yoo Sangjoon Hwang Jooyoung Lee

DRAM Design Team, Memory Division, Samsung Electronics

https://arxiv.org/pdf/2302.03591v1.pdf

Are We Now BitFlip Free?

- **Appears at ISCA 2023**

RowPress: Amplifying Read-Disturbance in Modern DRAM Chips

Haocong Luo Ataberk Olgun A. Giray Yağlıkçı Yahya Can Tuğrul Steve Rhyner
Meryem Banu Cavlak Joël Lindegger Mohammad Sadrosadati Onur Mutlu
ETH Zürich

RowPress [ISCA 2023]

- Haocong Luo, Ataberk Olgun, Giray Yaglikci, Yahya Can Tugrul, Steve Rhyner, M. Banu Cavlak, Joel Lindegger, Mohammad Sadrosadati, and Onur Mutlu,
  "RowPress: Amplifying Read Disturbance in Modern DRAM Chips"
  *Proceedings of the 50th International Symposium on Computer Architecture (**ISCA**)*, Orlando, FL, USA, June 2023.
  [Slides (pptx) (pdf)]
  [Lightning Talk Slides (pptx) (pdf)]
  [Lightning Talk Video (3 minutes)]
  [RowPress Source Code and Datasets (Officially Artifact Evaluated with All Badges)]
  Officially artifact evaluated as available, reusable and reproducible.
  Best artifact award at ISCA 2023.

RowPress: Amplifying Read-Disturbance in Modern DRAM Chips

Haocong Luo Ataberk Olgun A. Giray Yağlıkçı Yahya Can Tuğrul Steve Rhyner
Meryem Banu Cavlak Joël Lindegger Mohammad Sadrosadati Onur Mutlu
ETH Zürich

Emerging Memories Also Need Intelligent Controllers

- Benjamin C. Lee, Engin Ipek, Onur Mutlu, and Doug Burger, **"Architecting Phase Change Memory as a Scalable DRAM Alternative"** *Proceedings of the 36th International Symposium on Computer Architecture* (***ISCA***), pages 2-13, Austin, TX, June 2009. Slides (pdf)
  One of the 13 computer architecture papers of 2009 selected as Top Picks by IEEE Micro. Selected as a CACM Research Highlight.
  2022 Persistent Impact Prize.

Architecting Phase Change Memory as a Scalable DRAM Alternative

Benjamin C. Lee† Engin Ipek† Onur Mutlu‡ Doug Burger†

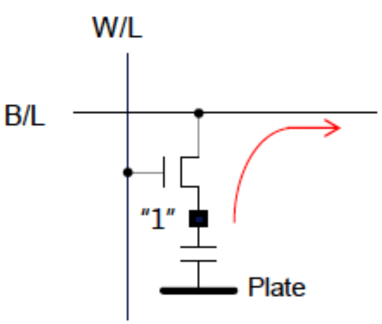
†Computer Architecture Group
Microsoft Research
Redmond, WA
{blee, ipek, dburger}@microsoft.com

‡Computer Architecture Laboratory
Carnegie Mellon University
Pittsburgh, PA
onur@cmu.edu

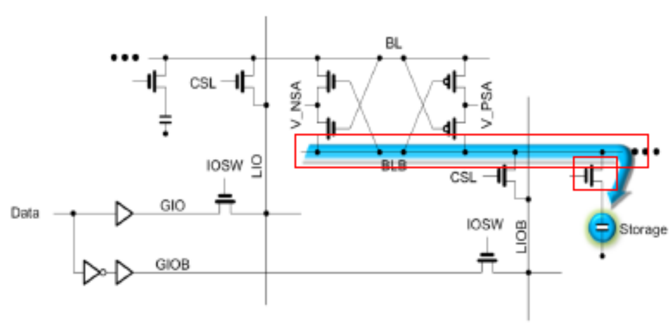
Industry Is Writing Papers About It, Too

DRAM Process Scaling Challenges

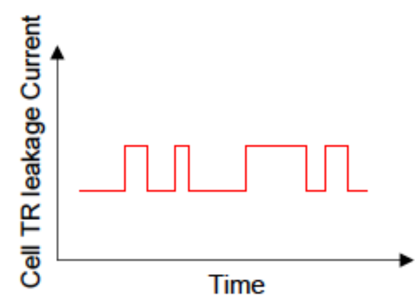
- **Refresh**
  - Difficult to build high-aspect ratio cell capacitors decreasing cell capacitance
  - Leakage current of cell access transistors increasing
- **tWR**
  - Contact resistance between the cell capacitor and access transistor increasing
  - On-current of the cell access transistor decreasing
  - Bit-line resistance increasing
- **VRT**
  - Occurring more frequently with cell capacitance decreasing



Refresh



tWR



VRT

Call for Intelligent Memory Controllers

DRAM Process Scaling Challenges

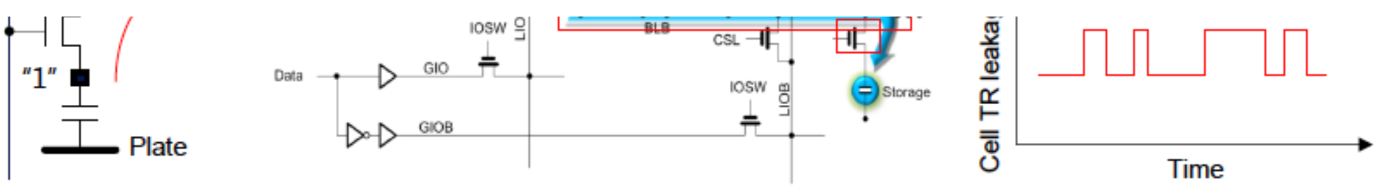
- **Refresh**
  - Difficult to build high-aspect ratio cell capacitors decreasing cell capacitance

THE MEMORY FORUM 2014

Co-Architecting Controllers and DRAM to Enhance DRAM Process Scaling

Uksong Kang, Hak-soo Yu, Churoo Park, *Hongzhong Zheng, **John Halbert, **Kuljit Bains, SeongJin Jang, and Joo Sun Choi

*Samsung Electronics, Hwasung, Korea / *Samsung Electronics, San Jose / **Intel*



Refresh **tWR** **VRT**

The Takeaway

Intelligent

Memory Controllers

Can Avoid Many Failures

& Enable Better Scaling

Three Key Systems & Application Trends

1. Data access is the major bottleneck
   - Applications are increasingly data hungry

2. Energy consumption is a key limiter

3. Data movement energy dominates compute
   - Especially true for off-chip to on-chip movement

Challenge and Opportunity for Future

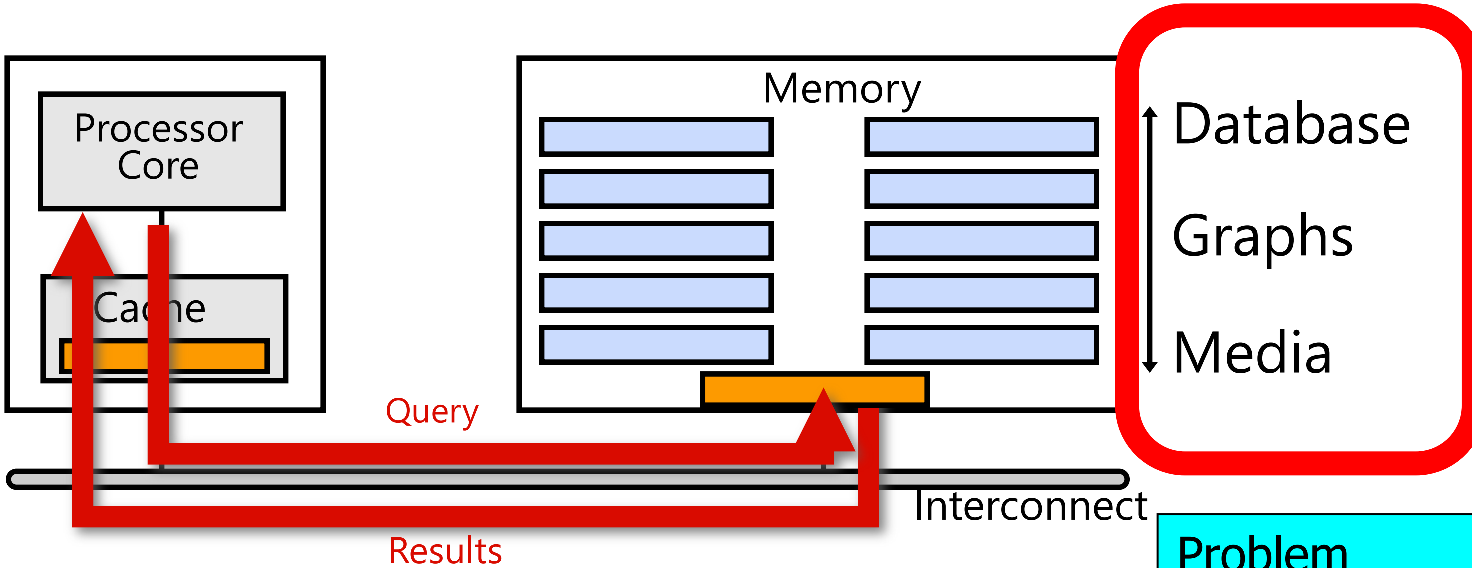
High Performance,

Energy Efficient,

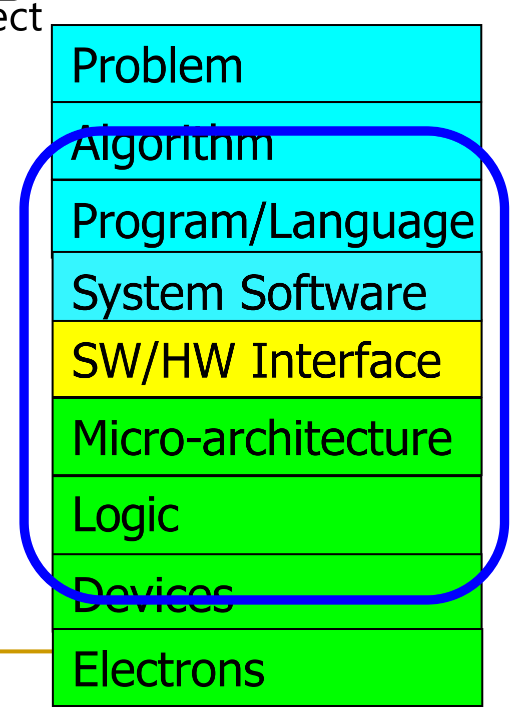
Sustainable

(All at the Same Time)

Goal: Processing Inside Memory



- Many questions … How do we design the:
  - compute-capable memory & controllers?
  - processors & communication units?
  - software & hardware interfaces?
  - system software, compilers, languages?
  - algorithms & theoretical foundations?



A Modern Primer on Processing in Memory

Onur Mutlu[a,b], Saugata Ghose[b,c], Juan Gómez-Luna[a], Rachata Ausavarungnirun[d]

SAFARI Research Group

[a] *ETH Zürich*
[b] *Carnegie Mellon University*
[c] *University of Illinois at Urbana-Champaign*
[d] *King Mongkut's University of Technology North Bangkok*

Onur Mutlu, Saugata Ghose, Juan Gomez-Luna, and Rachata Ausavarungnirun,
"A Modern Primer on Processing in Memory"
Invited Book Chapter in ***Emerging Computing: From Devices to Systems - Looking Beyond Moore and Von Neumann***, Springer, 2022.

Processing in Memory: Two Approaches

1. Processing near Memory
2. Processing using Memory

Two PIM Approaches

5.2. Two Approaches: Processing Using Memory (PUM) vs. Processing Near Memory (PNM)

Many recent works take advantage of the memory technology innovations that we discuss in Section 5.1 to enable and implement PIM. We find that these works generally take one of two approaches, which are categorized in Table 1: (1) *processing using memory* or (2) *processing near memory*. We briefly describe each approach here. Sections 6 and 7 will provide example approaches and more detail for both.

Table 1: Summary of enabling technologies for the two approaches to PIM used by recent works. Adapted from [341] and extended.

Approach	Example Enabling Technologies
Processing Using Memory	SRAM DRAM Phase-change memory (PCM) Magnetic RAM (MRAM) Resistive RAM (RRAM)/memristors
Processing Near Memory	Logic layers in 3D-stacked memory Silicon interposers Logic in memory controllers Logic in memory chips (e.g., near bank) Logic in memory modules Logic near caches Logic near/in storage devices

Onur Mutlu, Saugata Ghose, Juan Gomez-Luna, and Rachata Ausavarungnirun,
"A Modern Primer on Processing in Memory"
Invited Book Chapter in ***Emerging Computing: From Devices to Systems - Looking Beyond Moore and Von Neumann***, Springer, to be published in 2021.
[Tutorial Video on "Memory-Centric Computing Systems" (1 hour 51 minutes)]

Tutorial on Memory-Centric Computing: Introduction

Geraldo F. Oliveira
Prof. Onur Mutlu

HEART 2024
21 June 2024

SAFARI ETH zürich